

# Products Catalog

# **Fixed Resistors**

- General purpose chip resistors type
- High precision type
- Current sensing type
- Small & High power type

- Anti-Sulfurated type
- High temperature type
- Resistor network / Array type



# IN Your Future





# Fixed Resistors (Surface Mount Resistors) INDEX

Classification	Product item	Part No.	Page
<u>Safety</u> r	precautions (Common precautions for Fixed Resistors / Common pre	cautions for Surface Mount Resistors)	1
General purpose	Thick film chip resistors	ERJ XG, 1G, 2G, 3G, 6G, ERJ 8G*, 14*, 12*, 12Z*, 1T*	5
chip resistors	Precision thick film chip resistors	ERJ XG, 1G, 1R, 2R, 3R, 6R, 3E, 6E, 8E*, ERJ 14*, 12*, 1T*	8
	Thin film chip resistors, High voltage type	ERA 8P	12
High	Thin film chip resistors, High stability and reliability type	ERA 2V, 3V, 3K, 6V, 6K, 8V, 8K	14
precision	Metal film (Thin film) Chip resistors, High reliability type	ERA 1A, 2A, 3A, 6A, 8A	17
	High precision thick film chip resistors	ERJ PB3, PB6	20
Comment and in a	Thick film chip resistors / Low resistance type	ERJ 2LW, 3LW, 6LW, ERJ 2BW,3BW,6BW,8BW,6CW,8CW ERJ 2B, 3B, 6D, 6B, 8B, 14B, 3R, 6R, 8R, 14R, ERJ 12R, 12Z, ERJ 1TR, L03, L06, L08, L14, L12, L1D, L1W*	22
Current sensing	Current sensing resistors, Metal plate type	ERJ MS4S, MS4H, MB1S	28
	High power chip resistors / Wide terminal type	ERJ A1, B1, B2, B3	32
	Low TCR high power chip resistors / Wide terminal type	ERJ D1, D2	37
	Anti-Surge thick film chip resistors	ERJ PA2, P03, PA3, P06, P08, PM8, P14	40
Small & High power	Anti-Surge thick film chip resistors (Double-sided resistive elements structure)	ERJ P6W*	45
	Anti-Pulse thick film chip resistors	ERJ T06, T08, T14	47
	Anti-Sulfurated thick film chip resistors	ERJ S02, S03, S06, S08, S14, S12, S1D, S1T, ERJ U0X, U01, U02, U03, U06, U08, U14, U12, ERJ U1D, ERJ U1T, ERJ U6S, U6Q	50
Anti-Sulfurated	Anti-Sulfurated thick film chip resistors / Precision type	ERJ U2R, U3R, U6R	54
	Anti-Sulfurated thick film chip resistors / Anti-Surge type	ERJ UP3, UP6, UP8	56
Safety precautions (Common precautions for Fixed Resistors / Common precautions / Common precautions for Fixed Resistors / Common precautions / Common precautions for Fixed Resistors / Common precautions	ERJ C1	59	
High temperature	High temperature thick film chip resistors (Automotive Grade)	ERJ H2G, H2C, H2R, H3G, H3E, H3Q, H6G, HP6	62
	Chip resistor array	EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V	65
	Anti-Sulfurated chip resistor array	EXB U14, U18, U24, U28, U2H, U34, U38	69
network/Array	Chip resistor networks	EXB D, E, A, Q	72
	Chip attenuator	EXB 14AT, 24AT	76
	Packaging methods (Ta	aping)	78
Common	Recommended land pa	attern	83
specifications	Recommended soldering of	conditions	86
	Standard for resistance value and re	esistance tolerance	87



# Guidelines and precautions regarding the technical information and use of our products described in this online catalog.

- If you want to use our products described in this online catalog for applications requiring special qualities or reliability, or for applications where the failure or malfunction of the products may directly jeopardize human life or potentially cause personal injury (e.g. aircraft and aerospace equipment, traffic and transportation equipment, combustion equipment, medical equipment, accident prevention, anti-crime equipment, and/or safety equipment), it is necessary to verify whether the specifications of our products fit to such applications. Please ensure that you will ask and check with our inquiry desk as to whether the specifications of our products fit to such applications use before you use our products.
- The quality and performance of our products as described in this online catalog only apply to our products when used in isolation. Therefore, please ensure you evaluate and verify our products under the specific circumstances in which our products are assembled in your own products and in which our products will actually be used.
- Please ensure the safety by means of protection circuit, redundant circuit etc. in your system design in order to prevent the occurrence of life crisis and other serious damages due to the failure of our products.
- The products and product specifications described in this online catalog are subject to change for improvement without prior notice. Therefore, please be sure to request and confirm the latest product specifications which explain the specifications of our products in detail, before you finalize the design of your applications, purchase, or use our products.
- The technical information in this online catalog provides examples of our products' typical operations and application circuits. We do not guarantee the non-infringement of third party's intellectual property rights and we do not grant any license, right, or interest in our intellectual property.
- If any of our products, product specifications and/or technical information in this catalog is to be exported, the laws and regulations of the exporting country, especially with regard to security and export control, shall be observed.

# <Regarding the Certificate of Compliance with the EU RoHS Directive/REACH Regulations>

- The switchover date for compliance with the RoHS Directive/REACH Regulations varies depending on the part number or series of our products.
- When you use the inventory of our products for which it is unclear whether those products are compliant with the RoHS Directive/REACH Regulation, please select "Sales Inquiry" in the website inquiry form and contact us.

Please note that we do not owe any liability and responsibility if our products are used beyond the description of this catalog or without complying with precautions in this catalog.





# **Application Guidelines (Fixed Resistors)**

### 1. Safety precautions

- Make sure to exchange product specifications before using this product, regardless of the intended use. The design and specifications in this catalog are subject to change without prior notice.
- Do not use the products beyond the specifications described in this catalog.
- This catalog explains the quality and performance of the products as individual components. Before use, check and evaluate their operations when installed in your products under the actual conditions for use.
- If a malfunction of this product may result in the loss of human life or other serious damage in transportation equipment (trains, automobiles, ships, etc.), signaling equipment, medical equipment, aerospace equipment, electric heating equipment, combustion and gas equipment, rotating equipment, disaster prevention and security equipment, and other equipment, ensure safety by implementing a fail-safe design with the following system.
  - \* Systems equipped with a protection circuit and a protection device.
  - \* Systems equipped with a redundant circuit or other system to prevent an unsafe status in the event of a single fault.
  - \* Systems equipped with an arresting the spread of fire or preventing glitch.

#### 2. Precautions for use

- These products are designed and manufactured for general and standard use in general elec tron ic equipment. (e.g. AV equipment, home electric appliances, office equipment, information and communication equipment) If the product is to be used in an application that requires special quality and reliability and where failure or malfunction of the product may directly threaten human life or cause bodily harm (e.g., aerospace equipment, transportation equipment, combustion equipment, medical equipment, disaster prevention and security equipment, safety devices, etc.), be sure to consult with our sales office in advance and exchange product specifications appropriate for the application.
- These products are not intended for use in the following special conditions. Before using the products, carefully check the effects on their quality and performance, and determine whether or not they can be used.
  - 1. In liquid, such as water, oil, chemicals, or organic solvent.
  - 2. In direct sunlight, outdoors, or in dust.
  - 3. In salty air or air with a high concentration of corrosive gas, such as Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, or NO<sub>X</sub>.
  - 4. Electric Static Discharge (ESD) Environment.
    - These components are sensitive to static electricity and can be damaged under static shock (ESD). Please take measures to avoid any of these environments.
    - Smaller components are more sensitive to ESD environment.
  - 5. Electromagnetic and Radioactive Environment.
    - Avoid any environment where strong electromagnetic waves and radiation exist.
  - 6. In an environment where these products cause dew condensation.
  - 7. Sealing or coating of these products or a printed circuit board on which these products are mounted, with resin or other materials.
- These products generate Joule heat when energized. Carefully position these products so that their heat will not affect the other components.
- Carefully position these products so that their temperatures will not exceed the category temperature range due to the effects of neighboring heat-generating components. Do not mount or place heat-generating components or inflammables, such as vinyl-coated wires, near these products.
- Note that non-cleaning solder, halogen-based highly active flux, or water-soluble flux may deteriorate the performance or reliability of the products.
- Carefully select a flux cleaning agent for use after soldering. An unsuitable agent may deteriorate the performance or reliability. In particular, when using water or a water-soluble cleaning agent, be careful not to leave water residues. Otherwise, the insulation performance may be deteriorated.
- Do not apply flux to these products after soldering. The activity of flux may be a cause of failures in these products.
- Refer to the recommended soldering conditions and set the soldering condition. High peak temperature or long heating time may impair the performance or the reliability of these products.
- Recommended soldering condition is for the guideline for ensuring the basic characteristics of the products, not for the stable soldering conditions. Conditions for proper soldering should be set up according to individual conditions.
- Do not reuse any products after removal from mounting boards.
- Do not drop these products. If these products are dropped, do not use them. Such products may have received mechanical or electrical damage.
- If any doubt or concern to the safety on these products arise, make sure to inform us immediately and conduct technical examinations at your side.



#### 3. Precautions for storage

The performance of these products, including the solderability, is guaranteed for a year from the date of arrival at your company, provided that they remain packed as they were when delivered and stored at a temperature of 5 °C to 35 °C and a relative humidity of 45 % to 85 %.

Even within the above guarantee periods, do not store these products in the following conditions. Otherwise, their electrical performance and/or solderability may be deteriorated, and the packaging materials (e.g. taping materials) may be deformed or deteriorated, resulting in mounting failures.

- 1. In salty air or in air with a high concentration of corrosive gas, such as Cl2, H2S, NH3, SO2, or NOX.
- 2. In direct sunlight.

<Package markings>

Package markings include the product number, quantity, and country of origin. In principle, the country of origin should be indicated in English.

# 4. AEC-Q200 compliant

The products are tested based on all or part of the test conditions and methods defined in AEC-Q200. Please consult with Panasonic for the details of the product specification and specific evaluation test results, etc., make sure to exchange product specifications for each product when placing an order.



# 1

# **Application Guidelines (Surface Mount Resistors)**

The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

- Take measures against mechanical stress during and after mounting of Surface Mount Resistors
  (hereafter called the resistors) so as not to damage their electrodes and protective coatings.
   Be careful not to misplace the resistors on the land patterns. Otherwise, solder bridging may occur.
- 2. Keep the rated power and ambient temperature within the specified derating curve. Some circuit boards, wiring patterns, temperatures of heat generated by adjacent components, or ambient temper a tures can become factors in the rise of the temperature of the resistors, regardless of the level of power applied. Therefore, check the conditions before use and op timize them so as not to damage the boards and peripheral components.
  - Make sure to contact us before using the resistors under special conditions.
- 3. If a transient load (heavy load in a short time) like a pulse is expected to be applied, check and evaluate the operations of the resistors when installed in your products before use. Never exceed the rated power. Otherwise, the performance and/or reliability of the resistors may be impaired.
- 4. Transient voltage If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of resistors mounted on your product rather than only depending on the calculated power limit or steady-state conditions.
- 5. The electrical characteristics may change when used in high-frequency circuits, so check thoroughly before use. Such circuits change the electrical characteristics of the resistors.
- 6.Before using halogen-based or other high-activity flux, check the possible effects of the flux residues on the performance and reliability of the resistors.
- 7. When soldering with a soldering iron, never touch the resistors'bodies with the tip of the soldering iron. When using a soldering iron with a high temperature tip, finish soldering as quickly as possible (within three seconds at 350 °C max.).
- 8. The connection reliability and performance may be affected if the amount of solder is too much or too little. Check the performance and reliability of the product and use an appropriate amount of solder.
- 9. When the resistors' protective coatings are chipped, flawed, or removed, the characteristics of the resistors may be impaired. Take special care not to apply mechanical shock during automatic mounting or cause damage during handling of the boards with the resistors mounted.
- 10. Do not apply shock to the resistors or pinch them with a hard tool (e.g. pliers and tweezers). Otherwise, the resistors' protective coatings and bodies may be chipped, affecting their performance.
- 11. Avoid excessive bending of printed circuit boards in order to protect the resistors from abnormal stress.
- 12. Do not immerse the resistors in solvent for a long time.

  Before using solvent, carefully check the effects of immersion.
- 13. Do not apply excessive tension to the terminals.

# **Panasonic**

**INDUSTRY** 



# **Thick Film Chip Resistors**

**ERJ** type

ERJ XG, 1G, 2G, 3G, 6G series

ERJ 8G, 14, 12, 12Z, 1T series





(Oct. 2021) Products marked as "NRFND" are not recommended for new design. Target products: ERJ8G, 14, 12, 12Z, 1T series Please refer to the recommended alternatives with "Design Support Tool".

#### **Features**

Small size and lightweight

High reliability : Metal glaze thick film resistive element and three layers of electrodes

Compatible with placement machines : Taping packaging available

Suitable for both reflow and flow soldering

● Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

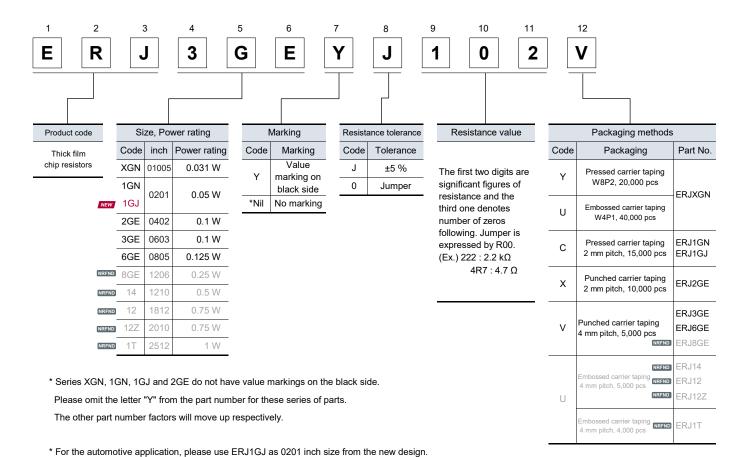
AEC-Q200 compliant (except ERJXG, ERJ1GN)

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**

● ERJXGN, 1GN, 1GJ, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T series, ±5 %



Not recommended for new design

# Ratings

#### [For Resistor]

	Part No. (inch size)	Rated power <sup>*1</sup> (70 ℃) (W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC-Q200 Grade
	ERJXG (01005)	0.031	15	30	±5	1 to 1 M	(E24)	R<10Ω : −100 to +600 10Ω to 100Ω : ±300 100Ω≤R : ±200		-
=	ERJ1GN (0201)	0.05	25	50	±5	1 to 10 M	to 10 M (E24)		-55 to +125	
NEV	ERJ1GJ (0201)	0.05	25	50	±5	1 to 10 M	(E24)	R<10 Ω : –100 to +600		Grade 1
_	ERJ2G (0402)	0.1	50	100	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200		
_	ERJ3G (0603)	0.1	75	150	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
	ERJ6G (0805)	0.125	150	200	±5	1 to 10 M	(E24)			
NRFN	ERJ8G (1206)	0.25	200	400	±5	1 to 10 M	(E24)			
NRFN	ERJ14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	R<10 Ω : -100 to +600		
NRFN	ERJ12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200	-55 to +155	Grade 0
NRFN	ERJ12Z (2010)	0.75	200	500	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
NRFN	ERJ1T (2512)	1	200	500	±5	1 to 1 M	(E24)			

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

#### [For Jumper]

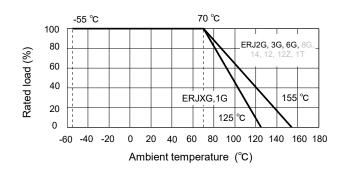
	Part No.	Resistance(Ω)	Rated current(A)	Maximum overload current (A)*1	
	ERJXG		0.5	1	
	ERJ1G		0.5	ı	
	ERJ2G	$50~\text{m}\Omega$ or less	1	2	
	ERJ3G		l		
	ERJ6G		2	4	
NRI	ERJ8G				
NRF	ERJ14				
NRF	ERJ12	$50~\text{m}\Omega$ or less	2	4	
NR	ERJ12Z				
NRF	ERJ1T				

<sup>\* 1 :</sup>Overload test current

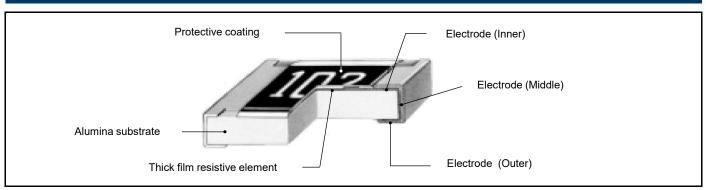
### Power derating curve

Not recommended for new design

above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



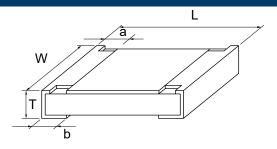
#### Construction



<sup>\*2:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

# Dimensions (not to scale)



Unit : mm

Part No.			Dimensions										
raitino.	L	W	а	b	Т	(Reference) (g/1000 pcs)							
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04							
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15							
ERJ2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8							
ERJ3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2							
ERJ6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4							
NREND ERJ8G	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10							
NREND ERJ14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16							
NRFND ERJ12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27							
NRFND ERJ12Z	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27							
NRFND ERJ1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45							

Not recommended for new design

# Performance

Test item	Performance re	equirements ⊿R	Test conditions		
i est item	Resistor type	Jumper type	rest conditions		
Resistance	Within specified tolerance	50 mΩ or less	20 ℃		
T. C. R.	Within specified T. C. R.	50 mΩ or less	+25℃ / +155℃ (ERJXG,1G : +25℃ / +125℃)		
Overload	±2 %	50 mΩ or less	Rated voltage× 2.5, 5 s  Jumper type: Max. overload current, 5 s		
Resistance to soldering heat	±1 %	50 mΩ or less	270 ℃, 10 s		
Rapid change of temperature	±1 %	50 mΩ or less	–55 ℃ (30 min.) / +155 ℃ (ERJXG,1G : +125 ℃) (30 min.), 100 cycles		
High temperature exposure	±1 %	50 mΩ or less	+155℃ (ERJXG,1G : +125℃), 1000 h		
Damp heat, Steady state	±1 %	50 mΩ or less	60 ℃, 90 % to 95 %RH, 1000 h		
			60 ℃, 90 % to 95 %RH,		
Load life in humidity	±3 %	$50~\text{m}\Omega$ or less	Rated voltage (Jumper type :Rated current),		
			1.5 h ON / 0.5 h OFF cycle, 1000 h		
	±3 %	50 mΩ or less	70℃, Rated voltage (Jumper type : Rated current),		
Endurance at 70℃	±3 70	50 mg or less	1.5 h ON / 0.5 h OFF cycle, 1000 h		

# **Panasonic**

**INDUSTRY** 



# **Precision Thick Film Chip Resistors**

**ERJ** type

ERJ XG, 1G series

ERJ 1R, 2R, 3R, 6R series

ERJ 3E, 6E, 8E, 14, 12, 1T series





(Oct. 2021) Products marked as "NRFND" are not recommended for new design. Target products: ERJ8E, 14, 12, 1Tseries Please refer to the recommended alternatives with "Design Support Tool".

#### **Features**

Small size and lightweight

High reliability : Metal glaze thick film resistive element and three layers of electrodes

Compatible with placement machines : Taping packaging available

Suitable for both reflow and flow soldering

● Low resistance tolerance : ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1T series : ±1 %

ERJ1R, 2R, 3R, 6R series : ±0.5 %

● Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

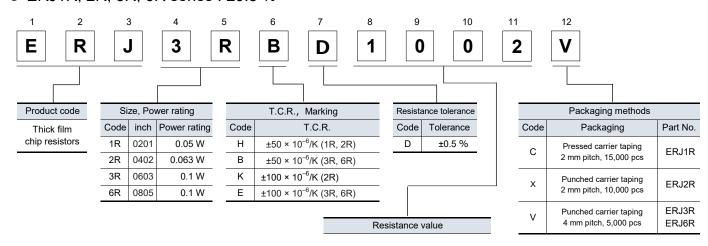
◆ AEC-Q200 compliant (except ERJ1R, ERJXG, ERJ1GN)

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**

ERJ1R, 2R, 3R, 6R series : ±0.5 %

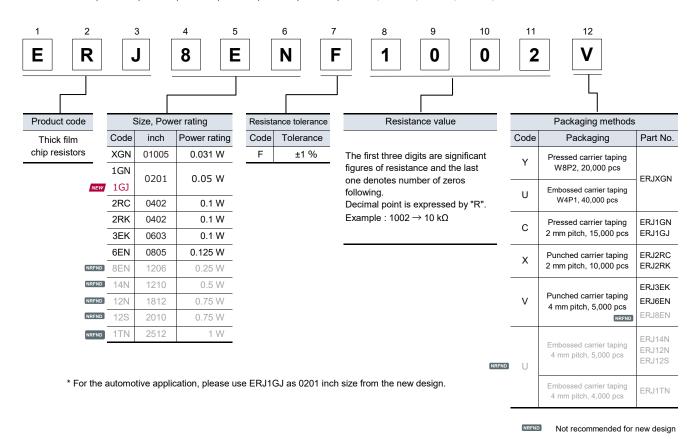


The first three digits are significant figures of resistance and the last one denotes number of zeros following.

Example :  $1002 \rightarrow 10 \text{ K}\Omega$ 

# **Explanation of part numbers**

ERJXGN, 1GN, 1GJ, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN series: ±1 %



#### **Ratings**

#### <±0.5 %>

Part No. (inch size)	Rated power <sup>*1</sup> (70 ℃) (W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	Resistance tolerance (%)	Resistance range $(\Omega)$		T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (°C)	AEC-Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1 k to 1 M	(E24,E96)	±50	-55 to +125	-
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100 k	(E24,E96)	±50	55 to +155	Grade 0
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		
ERJ3RB (0603)	0.1	75	150	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ3RE (0603)	0.1	75	150	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		

<sup>\*1 :</sup> Use it on the condition that the case temperature is below the upper category temperature.

<sup>\*2 :</sup> Rated continuous working voltage (RCWV) shall be determined from RCWV=\( \subseteq \text{Power rating} \times \text{Resistance value,} \) or limiting element voltage listed above, whichever less.

<sup>\*3 :</sup> Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

# **Ratings**

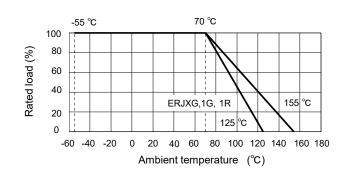
#### <±1 %>

	Part No. (inch size)	No. size) Power rating $^{\dagger}$ element over voltage $^{*2}$ volt		Maximum overload voltage <sup>*3</sup> (V)	Resistance tolerance (%) Resistance range (Ω)		nge	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (°C)	AEC-Q200 Grade
	ERJXGN (01005)	0.031	15	30	±1	10 to 1 M <sup>*4</sup>	(E24,E96)	R < 100 Ω : ±300 100 Ω ≤ R : ±200		_
	ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M <sup>*4</sup>	(E24,E96)	±200	-55 to +125	<u> </u>
NE	(0201)	0.05	25	50	±1	10 to 1 M <sup>*4</sup>	(E24,E96)	1200		Grade 1
	ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600	-55 to +155	Grade 0
	ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M	(E24,E96)			
	ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M	(E24,E96)	±100		
	ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M	(E24,E96)			
NRFI	(1206)	0.25	200	400	±1	10 to 2.2 M	(E24,E96)			
NRFI	ERJ14N (1210)	0.5	200	400	±1	10 to 1 M	(E24,E96)			Grade 0
NRFI	ERJ12N (1812)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	
NRFI	ERJ12S (2010)	0.75	200	500	±1	10 to 1 M	(E24,E96)			
NRFI	ERJ1TN (2512)	1	200	500	±1	10 to 1 M	(E24,E96)			

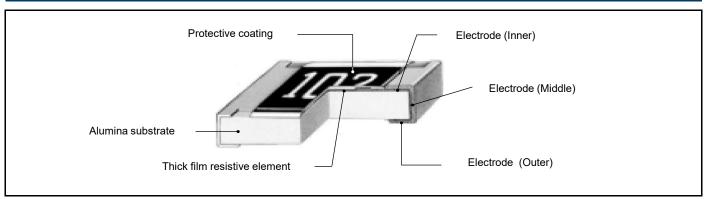
- \*1 : Use it on the condition that the case temperature is below the upper category temperature.
- \*2 : Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.
- \*3 : Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.
- \*4 : Please contact us when you need a type with a resistance of less than 10  $\Omega$ .

#### Power derating curve

For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.

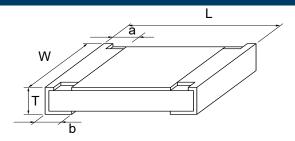


# Construction



Not recommended for new design

# **Dimensions (not to scale)**



Part No.			Dimensions (mm)			Mass (Weight)	
Fait No.	L	W	а	b	Т	(Reference) (g/1000 pcs)	
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04	
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15	
ERJ1R	0.00±0.03	0.30±0.03	0.10±0.00	0.10±0.00	0.2010.00	0.13	
ERJ2R	1.00±0.05	0.50±0.05	5 0.20±0.10 0.25±0.05 0.35±0		0.35±0.05	8.0	
ERJ3R	1.60±0.15	0±0.15 0.80+0.15/-0.05		0.30±0.15	0.45±0.10	2	
ERJ3E	1.00±0.10	0.00 10.10/-0.00	0.30±0.20	0.00±0.10	0.40±0.10	_	
ERJ6R	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4	
ERJ6E	2.0010.20	1.2020.10	0.4010.20	0.4020.20	0.0020.10		
NRFND ERJ8EN	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10	
NREND ERJ14N	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16	
NREND ERJ12N	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27	
NRFND ERJ12S	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27	
NRFND ERJ1TN	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45	

Not recommended for new design

# Performance

# ● ERJ1R, 2R, 3R, 6R series: ±0.5 % (D)

Test item	Performance	Test conditions			
rest item	requirements ⊿R	rest conditions			
Resistance	Within specified	20 ℃			
Resistance	tolerance	20 C			
T. C. R.	Within specified	+25 ℃ / +125 ℃			
1. O. N.	T. C. R.	+25 C/+125 C			
Overload ±2 %		Rated voltage × 2.5, 5 s			
Resistance to soldering heat ±1 %		270 ℃, 10 s			
Rapid change of temperature	±1 %	-55 °C (30 min.) / +155 °C (ERJ1R : +125 °C)(30 min.),			
Napid change of temperature	±1 /0	100 cycles			
High temperature exposure	±1 %	+155 ℃ (ERJ1R : +125 ℃), 1000 h			
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h			
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage,			
Load life in numbers	ERJ1R: ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 ℃	±2 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 C	ERJ1R : ±3 %	70 C, Rateu voltage, 1.5 ii ON / 0.5 ii OFF cycle, 1000 ii			

# ● ERJXGN, 1GN, 1GJ, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN series: ±1 % (F)

Test item	Performance requirements ⊿R	Test conditions		
Resistance	Within specified tolerance	20 ℃		
T. C. R.	Within specified T. C. R.	+25 °C / +155 °C (ERJXG,ERJ1G : +25 °C / +125 °C)		
Overload ±2 %		Rated voltage × 2.5, 5 s		
Resistance to soldering heat	±1 %	270 ℃, 10 s		
Rapid change of temperature	±1 %	–55 °C (30 min.)/+155 °C (ERJXG,ERJ1G : +125 °C)(30 min.), 100 cycles		
High temperature exposure	±1 %	+155 ℃ (ERJXG,ERJ1G : +125 ℃), 1000 h		
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h		
Load life in humidity	±2 % ERJXG,1G : ±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 ℃	±2 % ERJXG,1G : ±3 %	70 °C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

# **Panasonic**

**INDUSTRY** 

# Thin Film Chip Resistors, High Voltage Type

ERA P type

**ERA 8P** series



#### **Features**

High voltage : Achieves high limiting element voltage with original design concept (500V @1MΩ)

High reliability : Stable at high temperature and humidity

(85 °C 85 %RH rated load, Category temperature range : –55 °C to +155 °C)

High accuracy : Low resistance tolerance and temperature coefficient of resistance

High performance : Low current noise, excellent linearity

• Anti-ESD : Original structure for high ESD performance

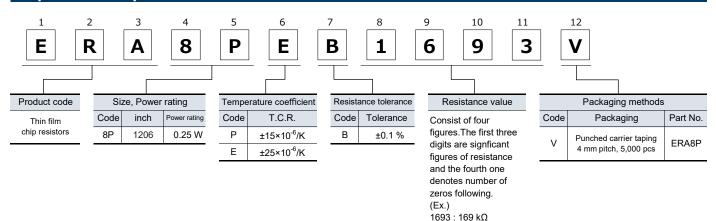
(AEC-Q200-002 HBM Guarantee at 4 kV)

Anti-sulfurated : Original structure for sulfurated performance
 Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**



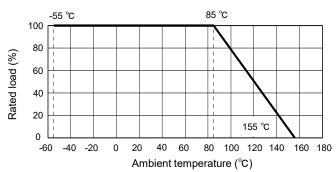
#### Ratings

Part No. (inch size)	Power rating at 85 ℃ <sup>*1</sup> (W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 <sup>-6</sup> /K)	Resistanc (Ω	U	Category temperature range (°C)	AEC-Q200 Grade
ERA8P	0.25	500	1000	ERA8PEB	±0.1	±25	160 k to 1 M	(E24, E96)	EE to 11EE	Grade 0
(1206)	0.25	500 1000	1000	ERA8PPB	PPB ±0.1	±15	TOURIOTIVI	(⊏∠4, ⊑90)	–55 to +155	Grade 0

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

#### Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.

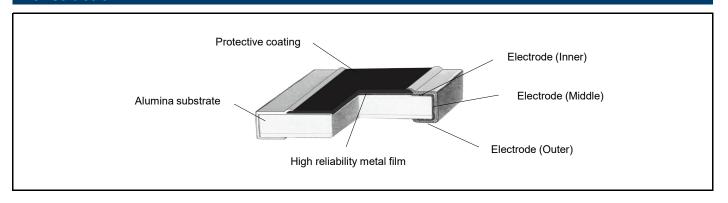


<sup>\*2:</sup> Rated continuous working voltage (RCWV) shall be determined from RCWV=√(Power Rating × Resistance Values), or limiting element voltage listed above, whichever less.

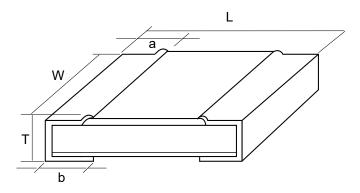
<sup>\*3:</sup> E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

# Thin Film Chip Resistors, High Voltage Type

# Construction



# **Dimensions (not to scale)**



Unit : mm

Part No.		Dimensions								
Fait NO.	L	W	а	b	Т	(Reference) (g/1000 pcs)				
ERA8P	3.20±0.20	1.60±0.10	0.50±0.20	0.50±0.20	0.55±0.10	10				

# **Performance**

Test Item	Performance	Test conditions				
	requirements ⊿R					
Resistance	Within specified	20.90				
Resistance	tolerance	20 ℃				
-	Within appoified					
T. C. R.	Within specified	+25 ℃ / +125 ℃				
	T. C. R.					
Overload	±0.1 %	Specified magnification (2.5) × RCWV or Maximum overload voltage,				
Overload	20.1 70	whichever less, 5 s				
Resistance to						
	±0.1 %	270 ℃, 10 s				
soldering heat						
Rapid change of	±0.1 %	55 % (00 min ) / 1455 % (00 min ) 4000 min -				
temperature	±0.1 %	$-55$ $^{\circ}$ C (30 min.) / +155 $^{\circ}$ C (30 min.), 1000 cycles				
· · · · · · · · · · · · · · · · · · ·						
High temperature	±0.1 %	+155 ℃, 1000 h				
exposure	-	100 0, 1000 11				
Damp heat,		_				
Steady state	±0.1 %	85 ℃, 85 %RH, 1000 h				
Load life in humidity	±0.1 %	85 ℃, 85 %RH, 10 % of Rated power <sup>*1</sup> ,				
Load life in numbers	±0.1 /6	1.5 h ON / 0.5 h OFF cycle , 1000 h				
End.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	±0.1 %	•				
Endurance at 85℃	±U.1 70	85 °C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h				
		$\Delta EC = 0.000 \text{ pcs}$ : 150 pF, 2000 $\Omega$ , positive 5 times,				
Electro static	±0.1 %	AEC-Q200-002 150 pF, 2000 Ω, positive 5 times, negative 5 times				
discharge (HBM)	±0.1 /0	<u> </u>				
		ERA8P : 4.0 kV (Class 3)				

<sup>\*1:</sup> Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ".

**INDUSTRY** 

# Thin Film Chip Resistors, **High Stability and Reliability Type**

**ERA V type** 

(High resistance value ERA K type)

ERA 2V, 3V, 6V, 8V series

(ERA 3K, 6K, 8K series)



#### **Features**

: To realize higher power rating, Limiting element voltage, and maximum High Power

overload voltage than current products

: Stable at high temperature and humidity High reliability

(85 °C 85 %RH rated load, Category temperature range : -55 °C to +155 °C)

 High accuracy : Low resistance tolerance and temperature coefficient of resistance

 High performance : Low current noise, excellent linearity

Anti-ESD : Original structure for high ESD performance

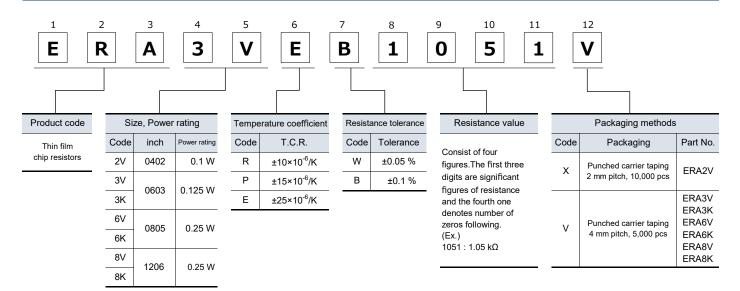
(AEC-Q200-002 HBM Class 1c and above)

 Anti-sulfurated : Original structure for sulfurated performance : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C Reference standard

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

# **Explanation of part numbers**



# Thin Film Chip Resistors, High Stability and Reliability Type

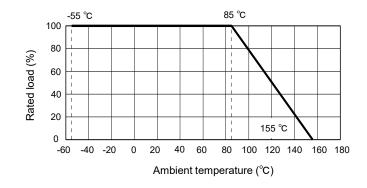
#### **Ratings**

Part No. (inch size)	Power rating at 85 ℃*1 (W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 <sup>-6</sup> /K)	Resistance range <sup>*4</sup> (Ω)	Category temperature range (°C)	AEC-Q200 Grade
				ERA2VEB	±0.1	±25	47 to 100 k <sup>*5</sup> (E24, E96)		
ERA2V	0.1	75	150	ERA2VPB	±0.1	±15			
(0402)	0.1	75	150	ERA2VRB	±0.1	±10	1 k to 47 k *5 (E24, E96)		
				ERA2VRW	±0.05	±10			
				ERA3VEB	±0.1	±25	47 to 100 k (E24, E96)		
ERA3V	0.125	100	200	ERA3VPB	±0.1	±15			
(0603)	0.125	100	200	ERA3VRB	±0.1	±10	1 k to 100 k (E24, E96)		
				ERA3VRW	±0.05	±10			
ERA3K (0603)	0.125	100	200	ERA3KEB	±0.1	±25	102 k to 240 k (E24, E96)		
			150 300	ERA6VEB	±0.1	±25	47 to 100 k (E24, E96)		
ERA6V	0.25	450		ERA6VPB	±0.1	±15		-55 to +155	Grade 0
(0805)	0.25	150		ERA6VRB	±0.1	±10	1 k to 100 k (E24, E96)		
				ERA6VRW	±0.05	±10			
ERA6K (0805)	0.25	150	300	ERA6KEB	±0.1	±25	102 k to 750 k (E24, E96)		
				ERA8VEB		±25	47 to 100 k (E24, E96)		
ERA8V	0.25	200	400	ERA8VPB	±0.1	±15	1 k to 100 k (E24, E96)		
(1206)	0.25	200	400	ERA8VRB		±10	1 k to 100 k (E24, E96)	=	
				ERA8VRW	±0.05	±10	1 K to 100 K (E24, E96)		
	ERA8K (1206) 0.25 200		ERA8KEB		±25	102 lete 1 M (F24 F06)	1		
ERA8K		200	200 400	ERA8KPB	A8KPB ±0.1	±15	102 k to 1 M (E24, E96)	_	
(1206)		200		ERA8KRB		±10	102 k to 160 k (E24, E96)		
	`			ERA8KRW	±0.05	110	102 K to 100 K (L24, E90)		

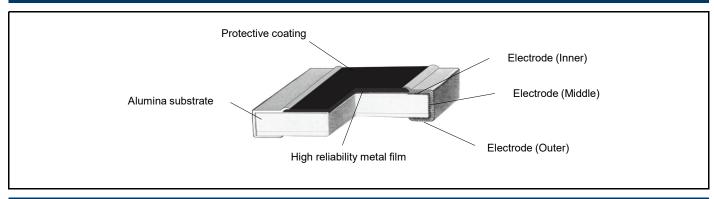
<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

#### Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.



### Construction



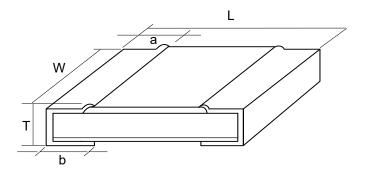
<sup>\*2:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

<sup>\*4:</sup> E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

<sup>\*5:</sup> Expanded resistance range

# Dimensions (not to scale)



Unit : mm

Part No.	Dimensions								
	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERA2V	1.00±0.05	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3V,3K	1.60±0.15	0.80±0.10	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6V,6K	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.55±0.10	5			
ERA8V,8K	3.20±0.20	1.60±0.10	0.50±0.20	0.50±0.20	0.55±0.10	10			

# Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±0.1 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±0.1 %	270 ℃, 10 s
Rapid change of temperature	±0.1 %	-55 °C (30 min.) / +155 °C (30 min.), 1000 cycles
High temperature exposure	±0.1 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.1 %	85 ℃, 85 %RH, 1000 h
Load life in humidity	±0.1 %	85 ℃, 85 %RH, 10 % of Rated power <sup>*1</sup> , 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 85℃	±0.1 %	85 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
		AEC-Q200-002 : 150 pF, 2000 Ω, positive 5 times, negative 5 times
Electro static	±0.1 % <sup>*2</sup>	ERA2V : 1.0 kV (Class 1c)
discharge (HBM)	±0.1 % <sup>-</sup>	ERA3V(3K) : 1.5 kV (Class 1c)
		ERA6V(6K) : 2.0 kV (Class 2)
		ERA8V(8K) : 2.0 kV (Class 2)

<sup>\*1:</sup> Applied Voltage is "√0.1 × Power Rating × Resistance Values", or "Limiting Element Voltage×0.316", whichever less.

<sup>\*2:</sup> Depends on resistance value.

# **Panasonic**

**INDUSTRY** 

# Metal Film (Thin Film) Chip Resistors, High Reliability Type

ERA A type

ERA 1A, 2A, 3A, 6A, 8A series



#### **Features**

High reliability : Stable at high temperature and humidity

(85 °C 85 %RH rated load, Category temperature range : –55 °C to +155 °C)

High accuracy : Low resistance tolerance and Temperature Coefficient of Resistance

High performance : Low current noise, excellent linearity

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C

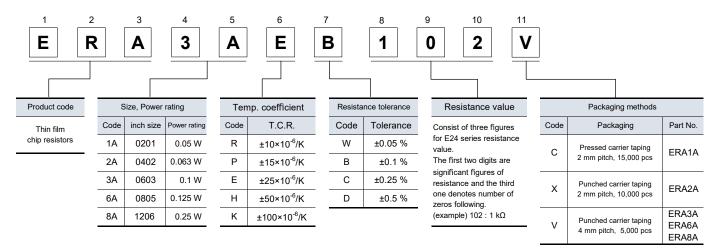
AEC-Q200 compliant (except ERA1A)

RoHS compliant

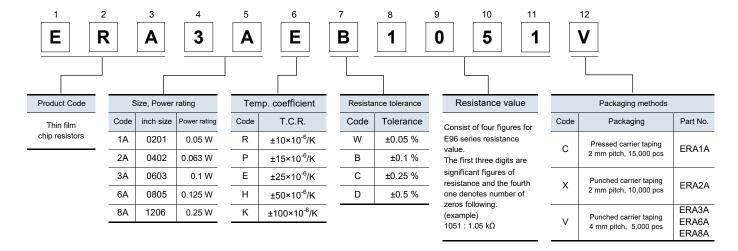
■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**

#### • E24 series



#### E96 series and other Resistance values



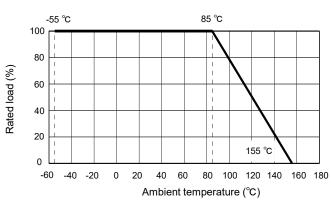
Note: Duplicated resistance values as E24 series part umbers shall follow E24 part numbers. (apply three digit resistance value)

#### Metal Film (Thin Film) Chip Resistors, High Reliability Type

#### **Ratings** Power Limiting Maximum Category Resistance Resistance element overload Part No. T.C.R. AEC-Q200 Part No. rating temperature range\*4 \*5 tolerance (inch size) voltage\*2 voltage\*3 (detail) range Grade (85 ℃) (×10<sup>-6</sup>/K) (%) (Ω) $(\mathcal{C})$ (W) (V) (V) **ERA1AEB** ±0.1 ±25 100 to 10 k (E24,E96) ERA1AEC ±0.25 ERA1A ±0.25 0.05 25 50 **ERA1ARC** (0201)(E24,E96) 100 to 10 k **ERA1ARB** ±0.1 ±10 1 k to 10 k (E24,E96) **ERA1ARW** ±0.05 ERA2AKD ±0.5 (E24,E96) ±100 10 to 46.4 ERA2AED ±0.5 **ERA2AEC** ±0.25 ±25 47 to 100 k (E24,E96) ERA2A ERA2AEB ±0.1 0.063 100 Grade 1 50 (0402)ERA2APC ±0.25 200 to 47 k ±15 (E24,E96) FRA2APB ±0.1 ERA2ARC ±0.25 ±10 200 to 47 k (E24.E96) **ERA2ARB** ±0.1 ERA3AHD 10 to 46.4 (E24,E96) ±0.5 ±50 **ERA3AED** ±0.5 ERA3AEC ±0.25 ±25 47 to 330 k (E24,E96) ERA3AEB ±0.1 ERA3A ±0.25 0.1 75 150 ERA3APC (0603)470 to 100 k (E24,E96) ±15 **ERA3APB** ±0.1 **ERA3ARC** ±0.25 -55 to +155 **ERA3ARB** 1 k to 100 k (E24,E96) ±0.1 ±10 **ERA3ARW** ±0.05 ERA6AHD (E24,E96) ±0.5 ±50 10 to 46.4 ERA6AED ±0.5 ERA6AEC ±0.25 47 to 1 M +25 (E24.E96) ERA6AEB ±0.1 ERA6A 0.125 100 200 ERA6APC ±0.25 Grade 0 (0805)470 to 100 k ±15 (E24,E96) **ERA6APB** ±0.1 **ERA6ARC** ±0.25 **ERA6ARB** 1 k to 100 k ±0.1 ±10 (E24,E96) **ERA6ARW** ±0.05 ERA8AHD ±0.5 (E24,E96) 10 to 46.4 ±50 ERA8AED ±0.5 ERA8AEC ±0.25 ±25 47 to 1 M (E24,E96) **ERA8AEB** ±0.1 ERA8A 0.25 150 300 FRA8APC ±0.25 (1206)470 to 100 k ±15 (E24,E96) **ERA8APB** ±0.1 ERA8ARC ±0.25 ERA8ARB ±0.1 ±10 1 k to 100 k (E24,E96) ERA8ARW ±0.05

#### Power derating curve

For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.



<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

<sup>\*2:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

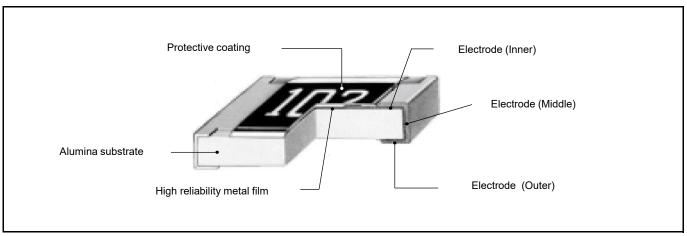
<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

<sup>\*4:</sup> E192 series resistance values are also available. Please contact us for details.

<sup>\*5:</sup> Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)

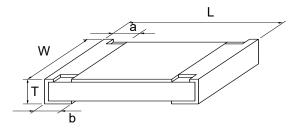
# Metal Film (Thin Film) Chip Resistors, High Reliability Type

# Construction



<sup>\*0201/0402</sup> size or E96 series do not have value markings.

# **Dimensions (not to scale)**



Unit : mm

Part No.	Dimensions								
Tarrito.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERA1A	0.60±0.03	0.30±0.03	0.15±0.05	0.15±0.05	0.23±0.03	0.14			
ERA2A	1.00±0.10	0.50+0.10/-0.05	0.15±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3A	1.60±0.20	0.80±0.20	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6A	2.00±0.20	1.25±0.10	0.40±0.25	0.40±0.25	0.50±0.10	4			
ERA8A	3.20±0.20	1.60+0.05/-0.15	0.50±0.25	0.50±0.25	0.60±0.10	8			

# Performance

·		
Test Item	Performance	Test conditions
i est item	requirements ⊿R	i est conditions
Resistance	Within specified	20 ℃
Resistance	tolerance	20 C
T. C. R.	Within specified	+25 ℃ / +125 ℃
1. U. K.	T. C. R.	+25 C/+125 C
Overload	R<47 Ω: ±0.5 %	Datad voltage v 2.5.5 c
Overload	R≧47Ω : ±0.1 %	Rated voltage x 2.5, 5 s
Resistance to	R<47 Ω: ±0.5 %	270 ℃, 10 s
soldering heat	R≧47Ω : ±0.1 %	270 C, 10 S
Rapid change	R<47 Ω: ±0.5 %	ERA1A, 2A: -55 ℃ (30 min.) / +125 ℃ (30 min.),1000 cycles
of temperature	R≧47Ω : ±0.1 %	ERA3A, 6A, 8A : –55 ℃ (30 min.) / +155 ℃ (30 min.),1000 cycles
High temperature	R<47 Ω: ±0.5 %	+155 ℃, 1000 h
exposure	R≧47Ω : ±0.1 %	+155 C, 1000 H
Damp heat,	R<47 Ω: ±0.5 %	85 ℃, 85 %RH, 1000 h
Steady state	R≧47Ω : ±0.1 %	03 C, 03 70KH, 1000 H
Load life in	R<47 Ω : ±0.5 %	85 ℃, 85%RH, 10% rated power, 1.5 h ON / 0.5 h OFF cycle, 1000 h,
humidity	R≥47Ω:±0.1 %	Max. test voltage : ERA2A : 15.8 V, ERA3A : 23.7 V, ERA6A : 31.6 V,
Hamilalty	1\=\tau_1\tau_2\tau_1\tau_1\tau_1	ERA8A : 47.4 V
Endurance at 85℃	R<47 Ω: ±0.5 %	95°C Detect violage 4.5 h ON / 0.5 h OFF evals 4000 h
Endurance at 65 C	R≧47Ω : ±0.1 %	85°C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

# **Panasonic**

**INDUSTRY** 

# **High Precision Thick Film Chip Resistors**

# ERJ PB type

ERJ PB3, PB6 series



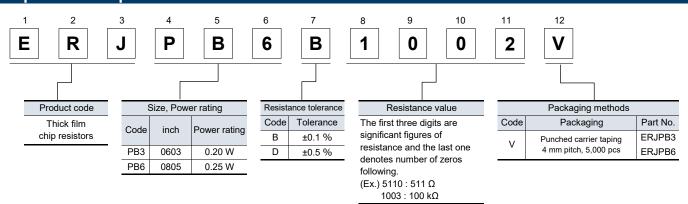
#### **Features**

- Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor
- Guarantee the temperature coefficient of Resistance ±50×10<sup>-6</sup>/K in high resistance range up to 1 MΩ
- High power : 0.20 W : 0603 inch /1608 mm size(ERJPB3)

: 0.25 W: 0805 inch /2012 mm size(ERJPB6)

- Reference Standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

# **Explanation of part numbers**



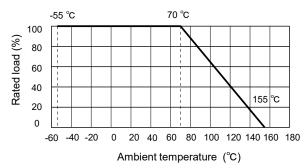
#### **Ratings**

Part No. (inch size)	Power rating <sup>*1</sup> (70 °C)(W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (°C)	AEC-Q200 Grade
ERJPB3 (0603)	0.20	150	200	±0.1 ±0.5	200 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
ERJPB6 (0805)	0.25	150	200	±0.1 ±0.5	200 to 1 M (E24, E96)	±50	-55 10 +155	Grade 0

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

#### Power derating curve

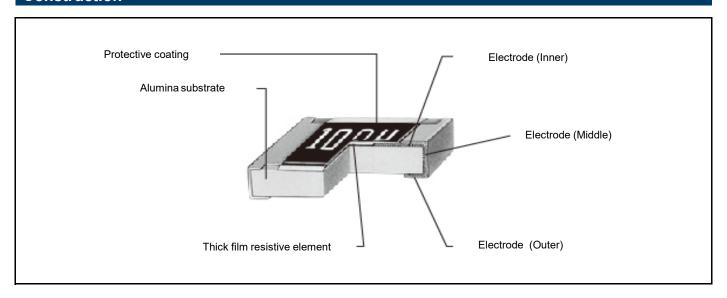
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



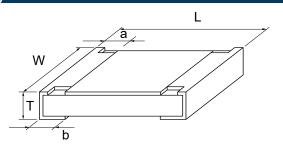
<sup>\*2:</sup> Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or Limiting Element Voltage listed above, whichever less.

<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum overload voltage listed above, whichever less.

# Construction



# Dimensions (not to scale)



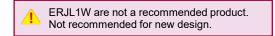
Unit : mm

Part No.	Dimensions								
raitino.	L	W	a b		Т	(Reference) (g/1000 pcs)			
ERJPB3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJPB6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			

# Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±0.5 %	Rated voltage× 2.0, 5 s
Resistance to soldering heat	±0.5 %	270 ℃, 10 s
Rapid change of temperature	±0.5 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High temperature exposure	±0.5 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.5 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±0.5 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±0.5 %	70 ℃, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h





\* Herr FO

# Thick Film Chip Resistors (Low Resistance Type)

ERJ type

ERJ 2LW, 3LW, 6LW series

ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series

ERJ 2B, 3B, 6D, 6B, 8B, 14B series

ERJ 3R, 6R, 8R, 14R, 12R, 12Z, 1TR series

ERJ L03, L06, L08, L14, L12, L1D, L1W series



- Current sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising

: ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW

● Low TCR : ±75×10<sup>-6</sup>/K(ERJ6CW, ERJ8CW)

• Low resistance value : Thick film resistors available from 5 mΩ (ERJ3LW, 6LW)

Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2144

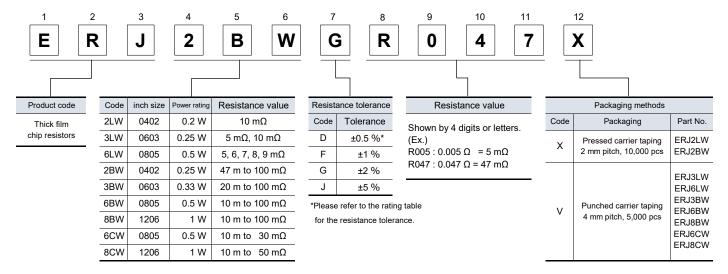
AEC-Q200 compliant

RoHS compliant

As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

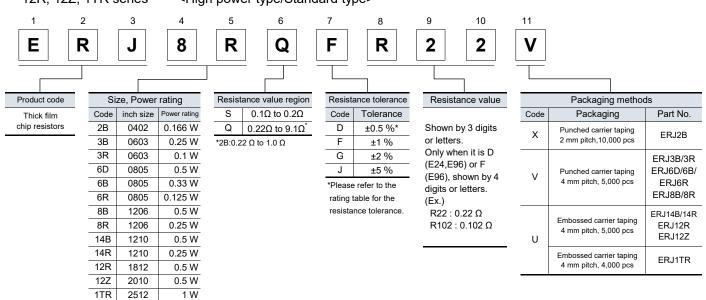
# **Explanation of part numbers**

ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series
 High power (double-sided resistive elements structure) type>

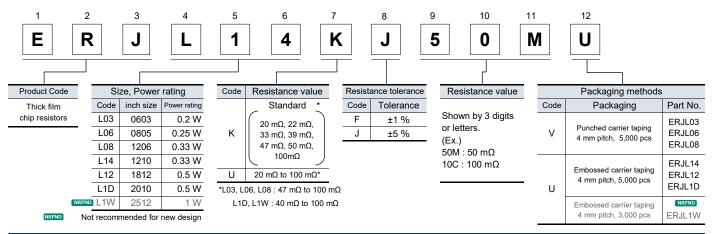


# **Explanation of part numbers**

• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR series <High power type/Standard type>



ERJL03, L06, L08, L14, L12, L1D, L1W series <Low TCR type>



#### Ratings

#### <High power (double-sided resistive elements structure) type>

Part No. (inch size)	Power rating (70 °C) <sup>*1</sup> (W)	Resistance tolerance (%)	Resistance range <sup>*2</sup> (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ2LW (0402)	0.2	±1, ±2, ±5	10 m	0 to +500		
ERJ3LW (0603)	0.25	±1, ±2, ±5	5 m	0 to +700	-55 to +125	Grade 1
LINGSEVV (0003)	0.25	11, 12, 10	10 m	0 to +300	-33 to 1123	
ERJ6LW (0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9 m	0 to +300		
ERJ2BW (0402)	0.25	±1, ±2, ±5	47 m to 100 m (E24)	0 to +300		
ERJ3BW (0603)	0.33	±1, ±2, ±5	20 m to 100 m (E24)	$20 \text{ m}\Omega \le R < 39 \text{ m}\Omega : 0 \text{ to } +250$		
LINJUN (0003)	0.33	11, 12, 13	20 111 10 100 111 (L24)	$39 \text{ m}\Omega \leq R \leq 100 \text{ m}\Omega : 0 \text{ to } +150$		
ERJ6BW (0805)	0.5	±1, ±2, ±5	10 m to 100 m (E24)	$10 \text{ m}\Omega \le R < 15 \text{ m}\Omega$ :0 to +300	-55 to +155	Grade 0
LINODVV (0003)	0.5	11, 12, 13	10 111 to 100 111 (L24)	$15 \text{ m}\Omega \leq R \leq 100 \text{ m}\Omega : 0 \text{ to } +200$	-33 10 +133	Grade 0
				$10 \text{ m}\Omega \le R < 20 \text{ m}\Omega : 0 \text{ to } +200$		
ERJ8BW (1206)	1	±1, ±2, ±5	10 m to 100 m (E24)	$20 \text{ m}\Omega \leq R \leq 47 \text{ m}\Omega : 0 \text{ to } +150$		
				$47 \text{ m}\Omega \leq R \leq 100 \text{ m}\Omega : 0 \text{ to } +100$		
ERJ6CW (0805)	0.5	±0.5, ±1, ±2, ±5	10 m to 30 m (E24)	±75	-55 to +125	Grade 1
ERJ8CW (1206)	1	±1, ±2, ±5	10 m to 50 m (E24)	±75	-00 10 +120	Giade I

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

<sup>\*2:</sup> Please contact us when resistors of irregular series are needed.

Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.

<sup>·</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

# Ratings

#### <High power type>

Part No. (inch size)	Power rating (70 °C) <sup>*1</sup> (W)	Resistance tolerance (%)	Resistand range <sup>*3</sup> (Ω)		T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ2BS (0402)	0.166	+1 +2 +5	0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ERJ2BQ (0402)	0.100	±1, ±2, ±5	0.22 to 1.0	(E24)	$0.22 \Omega \le R \le 1.0 \Omega$ : 0 to +250		
ERJ3BS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ED 12DO (0602)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +300$		
ERJ3BQ (0603)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ6DS (0805)			0.10 to 0.20	(E24 <sup>*2</sup> )	$0.10 \Omega \le R < 0.22 \Omega : 0 \text{ to } +150$		
ERJ6DQ (0805)	0.5	±0.5, ±1, ±2, ±5	0.22 to 9.1	(E24 <sup>*2</sup> )	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +100$		
EKJODQ (0003)			0.22 10 9.1	(E24 )	1.0 Ω ≤ R ≤ 9.1 Ω : ±100		
ERJ6BS (0805)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0
ED ISDO (0905)	0.33	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$		
ERJ6BQ (0805)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ8BS (1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ED 10DO (1206)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$		
ERJ8BQ (1206)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ14BS (1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ14BQ (1210)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
LN314BQ (1210)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±100		

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

<Standard type>

Part No. (inch size)	Power rating (70 °C) <sup>*1</sup> (W)	Resistance tolerance (%)	Resistand range $^{^{\star 2}}$ $(\Omega)$		T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ3RS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ERJ3RQ (0603)	0.1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~: 0 \text{ to } +300$		
L1031(Q (0003)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ6RS (0805)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ERJ6RQ (0805)	0.125	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~: 0 \text{ to } +250$		
LINUING (0003)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ8RS (1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ED 19DO (1206)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$		
ERJ8RQ (1206)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ14RS (1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ14RQ (1210)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \sim +200$	-55 to +155	Grade 0
LIN 14INQ (1210)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega$ : ±100		
ERJ12RS (1812)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ12RQ (1812)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
LIN 12INQ (1012)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ12ZS (2010)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ12ZQ (2010)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
EN3122Q (2010)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ1TRS (2512)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ED 11TDO (2512)	1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~: 0 \text{ to } +200$		
ERJ1TRQ (2512)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

<sup>\*2:</sup> E96 series resistance values are also available. Please contact us for details.

<sup>\*3:</sup> Please contact us when resistors of irregular series are needed.

<sup>•</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.

<sup>·</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

<sup>\*2:</sup> Please contact us when resistors of irregular series are needed.

<sup>•</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value.

<sup>·</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

# Thick Film Chip Resistors (Low Resistance Type)

# Ratings

<Low TCR type>

Part No. (inch size)	Power rating (70 °C) <sup>*1</sup> (W)	Resistance tolerance (%)	Resistance range <sup>*2</sup> (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJL03 (0603)	0.2	±1, ±5	47 m to 100 m	±200		
ERJL06 (0805)	0.25	±1, ±5	47 m to 100 m	±100		
ERJL08 (1206)	0.33	±1, ±5	47 m to 100 m	±100		
ERJL14 (1210)	0.33	±1, ±5	20 m to 100 m		-55 to +125	Grade 1
ERJL12 (1812)	0.5	±1, ±5	20 m to 100 m	R < 47 mΩ : ±300		
ERJL1D (2010)	0.5	±1, ±5	40 m to 100 m	$R \ge 47 \text{ m}\Omega: \pm 100$		
NRFND ERJL1W (2512)	1	±1, ±5	40 m to 100 m			

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

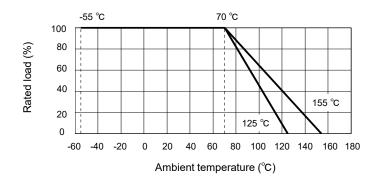
NRFND

Not recommended for new design

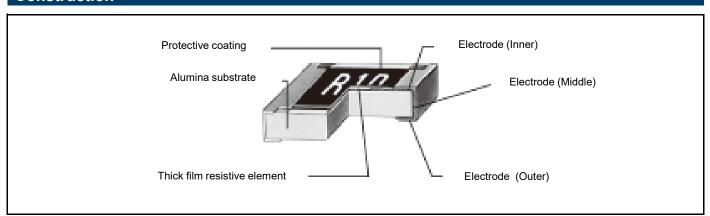
· Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

#### Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



#### Construction

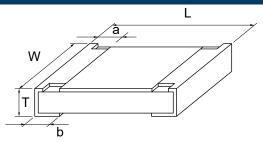


<sup>\*2:</sup> Standard R.V. : 20 m $\Omega$ , 22 m $\Omega$ , 33 m $\Omega$ , 39 m $\Omega$ , 47 m $\Omega$ , 50 m $\Omega$ , 100 m $\Omega$ , Custom R.V. : Each 1 m $\Omega$  within upper range.

<sup>•</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value.

# Thick Film Chip Resistors (Low Resistance Type)

# Dimensions (not to scale)



	Dimensions								
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERJ2LW	1.00±0.10	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.40±0.05	0.8			
ERJ2BW	1.00±0.10	0.50+0.10/-0.05	0.24±0.10	0.24±0.10	0.35±0.05	0.8			
ERJ2B	1.00±0.10	0.50+0.10/-0.05	0.20±0.10	0.27±0.10	0.35±0.05	0.8			
ERJ3LW (5 mΩ)	1.60±0.15	0.80±0.15	0.50±0.20	0.50±0.20	0.55±0.10	3			
ERJ3LW (10 mΩ) ERJ3BW	1.60±0.15	0.80±0.15	0.40±0.20	0.40±0.20	0.55±0.10	3			
ERJ3R ERJ3B ERJL03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJ6LW	2.00±0.20	1.25±0.20	0.63±0.20	0.63±0.20	0.70±0.10	6			
ERJ6BW	2.00±0.20	1.25±0.20	0.55±0.20	0.55±0.20	0.65±0.10	6			
ERJ6CW (10 to 13 mΩ)	0.05.0.00	4.00.0.00	0.60±0.20	0.60±0.20	0.05.0.40				
ERJ6CW (15 to 30 mΩ)	2.05±0.20	1.30±0.20	0.45±0.20	0.45±0.20	0.65±0.10	6			
ERJ6D	2.00±0.20	1.25±0.10	0.40±0.20	0.55±0.25	0.60±0.10	5			
ERJ6R ERJ6B ERJL06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	5			
ERJ8BW	3.20±0.20	1.60±0.20	1.00±0.20	1.00±0.20	0.65±0.10	13			
ERJ8CW (10 to 16 mΩ)	3.20±0.20	1.60±0.20	1.10±0.20	1.10±0.20	0.65±0.10	13			
ERJ8CW (18 to 50 mΩ)	3.20±0.20	1.60±0.20	0.60±0.20	0.60±0.20	0.65±0.10	13			
ERJ8R ERJ8B ERJL08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJ14R ERJ14B ERJL14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJ12R ERJL12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJ12Z ERJL1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJ1TR	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			
NRFND ERJL1W	6.40±0.20	3.20±0.20	0.65±0.20	1.30±0.20	1.10±0.10	79			

Not recommended for new design

# Performance

• ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series <High power (double-sided resistive elements structure) type>

Test item	Performance requirements ⊿R	Test conditions		
Resistance	Within specified tolerance	20 ℃		
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃		
Overload	±2 %	ERJ6LW : Rated voltag× 1.77, 5 s  ERJ8BW (R > 0.05 Ω) : Rated voltag× 1.77, 5 s  Other : Rated voltag× 2.0, 5 s		
Resistance to soldering heat	±1 %	270 ℃, 10 s		
Rapid change of temperature	±1 % ERJ2LW : ±2 %	–55 ℃ (30min.) / +155 ℃ (ERJ□LW, ERJ□CW : +125 ℃) (30 min.), 100 cycles		
High temperature exposure	±1 %	+155 ℃ (ERJ□LW, ERJ□CW : +125 ℃), 1000 h		
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h		
Load life in humidity ±3 %		60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR series < High power type/Standard type>

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltage× 2.5 (ERJ6D : ×1.77 ), 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

#### ● ERJL03, L06, L08, L14, L12, L1D, L1W series < Low TCR type >

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 °C (30 min.) / +125 °C (30 min.), 100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

# **Panasonic**

**INDUSTRY** 

# Current Sensing Resistors, Metal Plate Type ERJ MS, MB type

EKJ WIS, WIB type

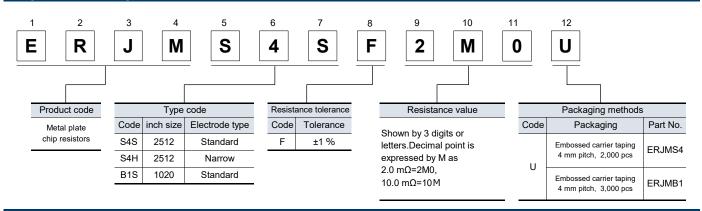
ERJ MS4, MB1 series



#### **Features**

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- Outer Resin with high heat dissipation. Wide temperature range (-65 °C to +170 °C)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

# **Explanation of part numbers**



Ratings							
Part No. (inch size)	Power rating (70 ℃) (W)	Resistance range (mΩ)	Resistance tolerance (%)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	Terminal temp. upper limit (℃)	AEC-Q200 Grade
ERJMS4S (2512)	3	1, 2, 3, 4	F : ±1	±75		130	
ERJMS4H	3	5, 6	F:±1	±75	-65 to +170		Grade 0
(2512)	2	7, 8, 9, 10	F:±1	±75	-03 10 +170	100	Grade 0
ERJMB1S (1020)	2	1, 2, 3, 4, 5	F : ±1	±75		130	

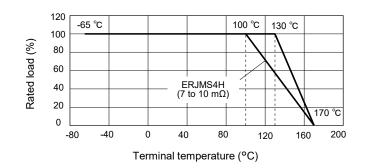
<sup>\*</sup> Please contact us when resistors of irregular series are needed.

#### Power derating curve

If the terminal temperature of the resistor is more than terminal temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right. <Supplemented>

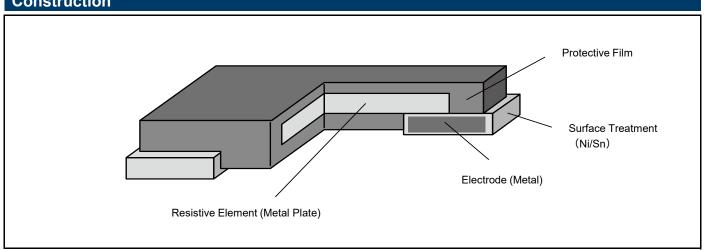
In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.

- Terminal temperature measurement, please apply the temperature of the higher of either the left or right electrode upper surface of the resistor.
- Please measure the temperature of the resistor in the land pattern printed of circuit board and plan to use by real conditions.



# **Current Sensing Resistors, Metal Plate Type**

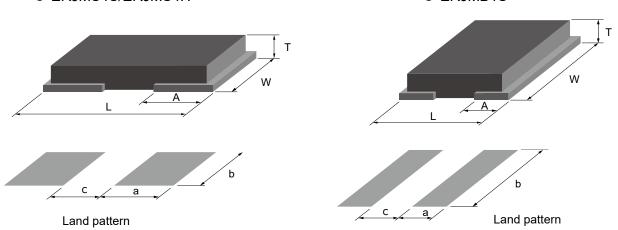
# Construction



# Dimensions in mm (not to scale), Recommended land pattern







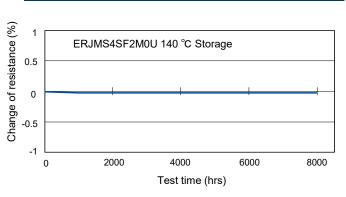
Unit: mm

Part No.		Dime	Recom	Mass (Weight) (Reference)				
	L	W	А	Т	а	b	С	(g/1000 pcs)
ERJMS4S	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120
ERJMS4H	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115
ERJMB1S	2.55±0.25	5.00±0.25	0.68 +0.15/-0.20	0.90±0.15	1.15	5.5	1.1	40

#### Typical temp. dependence of electrical resistance

# Change of resistance (%) 0.5 0 -0.5 -80 -60 -40 -20 20 40 60 80 100 120 140 160 180 Temperature (°C)

# Long-term stability



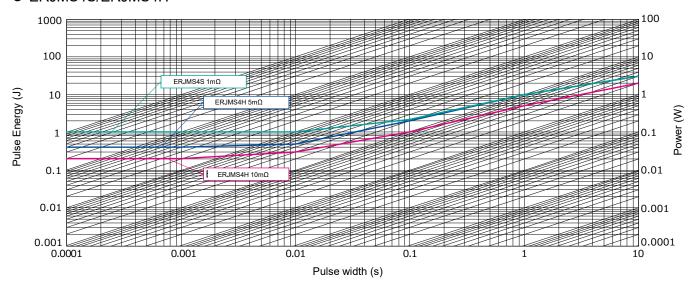
# Maximum pulse energy respectively pulse power for continuous operation

Referance Data

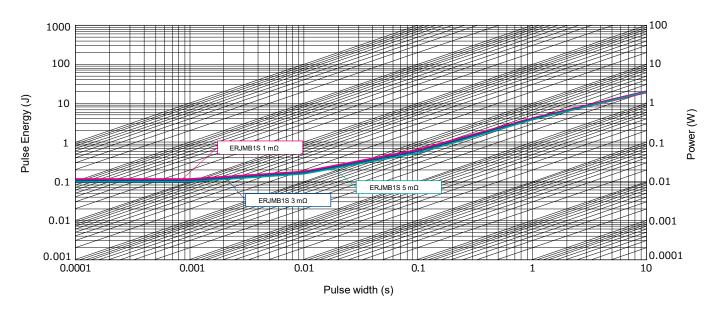
Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square

Change of Resistance = ±1 %

#### ERJMS4S/ERJMS4H



#### • ERJMB1S



# Performance (AEC-Q200)

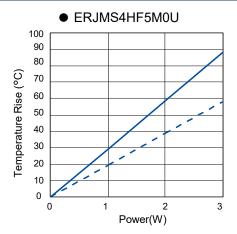
#### ERJMS4S/ERJMS4H

Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.20 %	-55 ℃ / +155 ℃, 1000 cycles
Overload	±0.5 %	0.10 %	Rated power x 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

#### ERJMB1

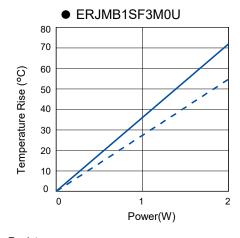
Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.30 %	-55 ℃ / +155 ℃, 1000 cycles
Overload	±1 %	0.30 %	Rated power x 2.5, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

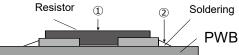
# Temperature rise



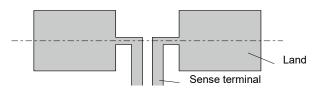
<Condition>

Base material: FR-4 (t 1.6 mm) Copper Thickness : 70 µm, Two layer





# Sense terminal-Layout



# **Panasonic**

INDUSTRY

# High Power Chip Resistors (Wide Terminal Type)

ERJ A, B type

ERJ A1, B1, B2, B3 series

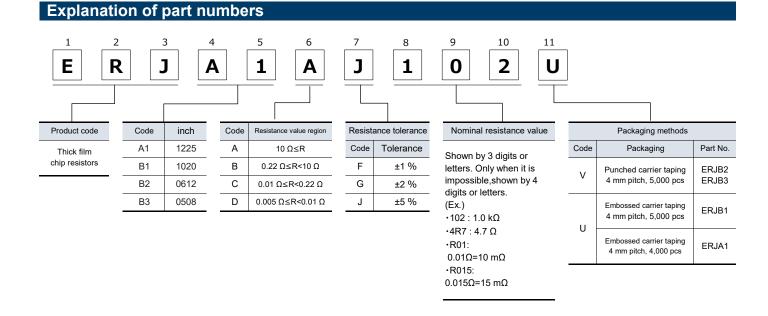


#### **Features**

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

#### **Recommended applications**

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.



# **High Power Chip Resistors (Wide Terminal Type)**

# Ratings

Part No. (inch size)	Power rating*1 (W)	Rated ambient temperature*2	Rated terminal part temperature*2	Limiting element voltage <sup>*3</sup> (V)	Maximum overload voltage*4 (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC- Q200 Grade	
ERJA1	1.33	70		200	400	±1	100m to 10k (E24)	±100			
(1225)	1.33	70	-	200	400	±2, ±5	10m to 10k (E24)	10mΩ≤R<100mΩ : ±350 100mΩ≤R≤10kΩ : ±200			
						±1	40 4 40	±1 % : 10mΩ≤R<22mΩ : 0 to +350			
ERJB1	2 (R≤10Ω)	70	125	200	400	±2, ±5	10m to 10 (E24)	22mΩ≤R<47mΩ : 0 to +200 47mΩ≤R<100mΩ : 0 to +150 100mΩ≤R≤10kΩ : ±100		Grade 0	
(1020)	1	1	95			±1	11 to 10k	±2 %, ±5 % : 10mΩ≤R<22mΩ : 0 to +350			
	(R>10Ω)	70	93			±2, ±5	(E24)	22mΩ≤R<100mΩ : 0 to +200 100mΩ≤R≤10kΩ : ±200			
	1.5 (R≤1kΩ)	-	125	-	400	±1 ±2, ±5	10m to 1k (E24)	±1 % :	<b>−55 ~ +155</b>		
	0.75 (R>1k $\Omega$ )	-	90			±1 ±2, ±5	1.1k to 1M (E24)	10mΩ≤R<22mΩ : 0 to +300 22mΩ≤R<47mΩ : 0 to +200			
						±1	10m to 10 (E24)	$47$ mΩ $\leq$ R $<$ 100mΩ : 0 to +150 $100$ mΩ $\leq$ R $\leq$ 220mΩ : 0 to +100			
ERJB2 (0612)	1 (R≤10Ω)	70	-	200		400	400	±5	5, 6, 7, 8, 9,10m to 10 (E24)	$220m\Omega \le R \le 1M\Omega : \pm 100$ $\pm 2 \%, \pm 5 \% :$ $5m\Omega \le R < 22m\Omega : 0 \text{ to } +300$ $22m\Omega \le R < 47m\Omega : 0 \text{ to } +200$ $47m\Omega \le R < 100m\Omega : 0 \text{ to } +150$ $100m\Omega \le R < 220m\Omega : 0 \text{ to } +200$	
	0.75 (R>10Ω)	70				±1 ±2, ±5	11 to 1M (E24)	220mΩ≤R≤1MΩ : ±200			
	1	-	105			±1 ±2, ±5	20m to 10 (E24)	$\pm 1\%$ : $20m\Omega \le R < 47m\Omega$ : 0 to +300 $47m\Omega \le R < 1\Omega$ : 0 to +200			
ERJB3 (0508)	0.5 (R≤1Ω)	70	-	150	200	±1 ±2, ±5	20m to 1 (E24)	1Ω≤R≤10Ω : ±100 ±2 %, ±5 % : 20mΩ≤R<47mΩ : 0 to +300			
	0.33 (R>1Ω)	70	-			±1 ±2, ±5	1.1 to 10 (E24)	47mΩ≤R<1Ω: 0 to +200 1Ω≤R≤10Ω: ±200			

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

<sup>\*2:</sup> If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

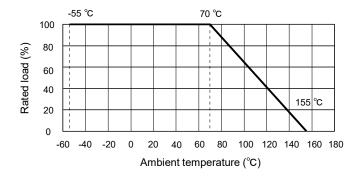
<sup>\*3:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

<sup>\*4:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

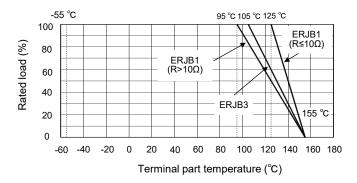
# **Ratings**

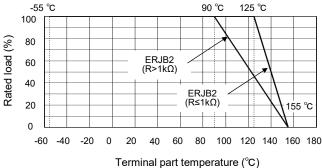
#### Power derating curve

- For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.
  - In addition, please use under the condition that the product temperature is below the upper category temperature.

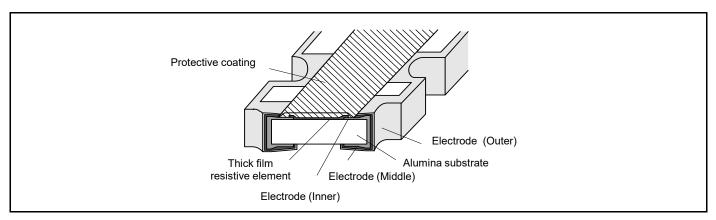


- For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.
  - In addition, please use under the condition that the product temperature is below the upper category temperature.



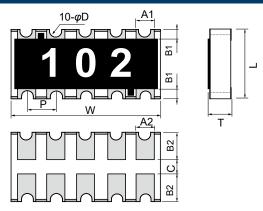


# Construction (Example : ERJA1 type)



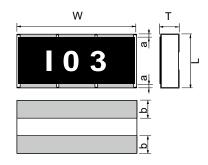
# **High Power Chip Resistors (Wide Terminal Type)**

# Dimensions (not to scale)



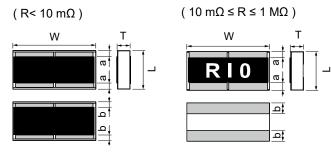
Unit : mm

Part No.	Dimensions							
Fait No.	L	W	A <sub>1</sub>	B <sub>1</sub>	Т	(Reference) (g/1000 pcs)		
	3.20±0.20	6.40±0.20	0.70±0.20	0.45±0.20	0.55±0.10			
ERJA1	$A_2$	$B_2$	Р	øD	С	40		
	0.70±0.20	1.25±0.15	1.27±0.10	0.30+0.10/-0.20	0.4 min.			



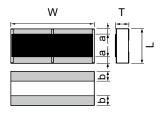
Unit : mm

Part No.	Dimensions						
Fait No.	L	W	а	b	T	(Reference) (g/1000 pcs)	
ERJB1	2.50±0.20	5.00±0.20	0.25±0.20	0.90±0.20	0.55±0.20	27	



Unit : mm

Part No.		Dimensions						
ERJB2	L	W	а	b	Т	(Reference) (g/1000 pcs)		
5 mΩ≤R<10 mΩ			0.30±0.20	0.30±0.20	0.65±0.15			
10 mΩ≤R<220 mΩ	1.60±0.15	3.20±0.20	0.30±0.20	0.50±0.20	0.55±0.15	11		
220 mΩ≤R≤1 MΩ			0.25±0.20	0.50±0.20	0.55±0.15			

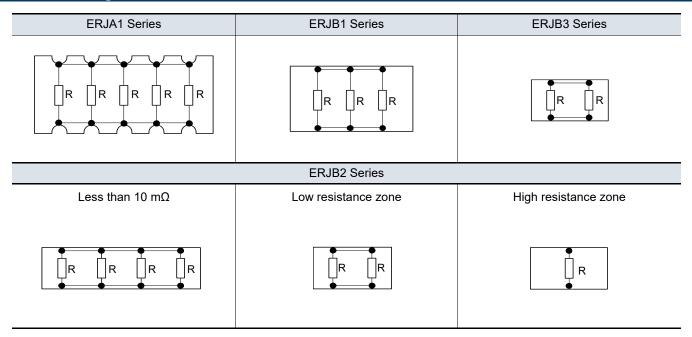


Unit: mm

Part No.	Dimensions						
Fait No.	L	W	а	b	Т	(Reference) (g/1000 pcs)	
ERJB3	1.25±0.10	2.00±0.15	0.25±0.20	0.40±0.20	0.50±0.10	4.8	

# **High Power Chip Resistors (Wide Terminal Type)**

# Circuit configuration



Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	ERJA1, ERJB1 (1W): Rated voltag x 2.5, 5 s  ERJB2 (0.75 W): Rated voltag x 2.2, 5 s  ERJB1 (2 W), ERJB2 (1.5 W, 1 W), ERJB3: Rated voltag x 2.0, 5 s
Resistance to soldering heat	±1 %	270℃, 10 s
Rapid change of temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated ambient temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

**INDUSTRY** 

# Low TCR High Power Chip Resistors (Wide Terminal Type)

.010

ERJ D type

ERJ D1, D2 series

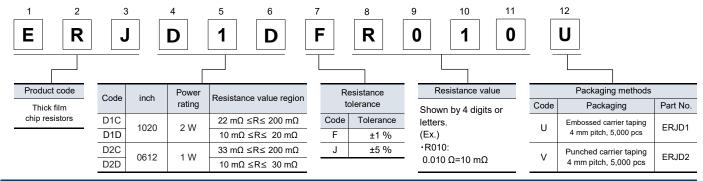
#### **Features**

- Achieved High power and low TCR (±100×10<sup>-6</sup>/K) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

#### Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**



#### **Ratings**

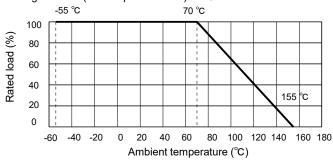
Part No. (inch size)	Power rating (70 ℃) <sup>*1</sup> (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJD1 (1020)	2	±1, ±5	10 m to 200 m (E24)	±100	-55 to +155	Grade 0
ÉRJD2 (0612)	1	±1, ±5	10 m to 200 m (E24)	±100	-55 10 +155	Grade 0

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

- · Please contact us when resistors of irregular series are needed.
- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.
- · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV.

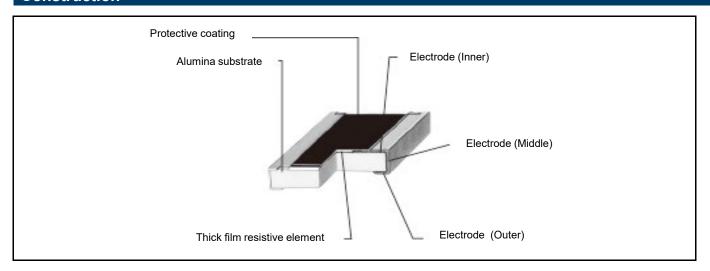
#### Power derating curve

For resistors operated in ambient temperatures above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.

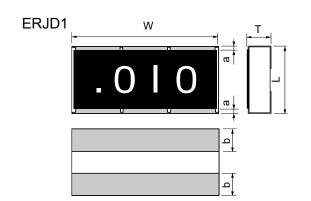


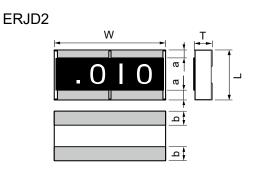
# **Low TCR High Power Chip Resistors (Wide Terminal Type)**

# Construction



# Dimensions (not to scale)

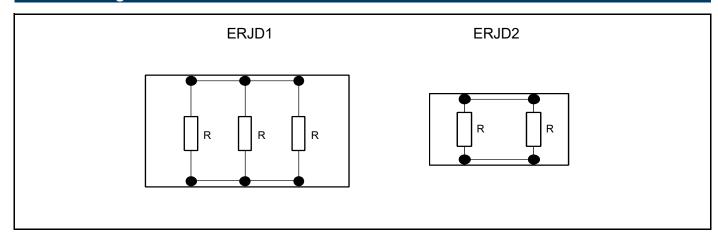




Unit : mm

Part No.	Dimensions						
L L	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJD1	2.50±0.20	5.00±0.20	0.30±0.20	0.90±0.20	0.60±0.20	27	
ERJD2	1.60±0.15	3.20±0.20	0.30±0.20	0.50±0.20	0.65±0.15	11	

# **Circuit configuration**



# Low TCR High Power Chip Resistors (Wide Terminal Type)

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltag x 2.0, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

**INDUSTRY** 

# **Anti-Surge Thick Film Chip Resistors**

ERJ P, PA,PM type

ERJ PA2, PA3, P03, P06, P08, PM8, P14 series



Embossed carrier taping

4 mm pitch, 5,000 pcs

U

#### **Features**

• ESD surge characteristics superior to standard metal film resistors

High reliability : Metal glaze thick film resistive element and three layers of electrodes

Suitable for both reflow and flow soldering

High power 0.20 W: 0603 inch / 1608 mm size (ERJP03)

0.20~W:0402~inch~/~1005~mm~size~(ERJPA2) 0.33~W:0603~inch~/~1608~mm~size~(ERJPA3)

0.50 W: 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)

0.66 W: 1206 inch / 3216 mm size (ERJP08)

High precision, High voltage, High resistance value (ERJPM8)

: Limiting element voltage 500 V, Resistance tolerance ±1 %, TCR ±100 (x 10<sup>-6</sup> / K)

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

AEC-Q200 compliant

**Explanation of part numbers** 

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### Ε P R 0 6 D 0 0 Product code Code Nominal resistance value inch size Resistance tolerance Packaging methods Packaging PA2 0402 Code Tolerance Code Part No. Thick film Three digit type (±5 %), chip resistors PA3 D ±0.5 % Four digit type (±1 %, ±0.5 %) Punched carrier Ttaping 0603 Χ ERJPA2 Example: 2 mm pitch, 10,000 pcs P03 F ±1% 222 : 2.2 KΩ P06 0805 +5 % 10R0 : 10 Ω J ERJPA3 1002 : 10 ΚΩ ERJP03 P08 Punched carrier taping ERJP06 1206 V 4 mm pitch, 5,000 pcs PM8 ERJP08 ERJPM8 P14 1210

ERJP14

# **Anti-Surge Thick Film Chip Resistors**

# Ratings

rtating																	
Part No. (inch size)	Power rating*1 (W)	Rated ambient temperature*2	Rated terminal part temperature*2	Limiting element voltage <sup>*3</sup> (V)	Maximum overload voltage <sup>*4</sup> (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC- Q200 Grade							
	0.20	70	-			±0.5, ±1	10 to 1M (E24, E96)										
ERJPA2	0.20	70	-	50	100	±5	10 to 1M (E24)	±0.5, ±1 : ±100		Grade 1							
(0402)	0.25	_	100	30	100	±0.5, ±1	10 to 1M (E24, E96)	±5:±200		Grade 1							
	0.20	-	100			±5	10 to 1M (E24)										
	0.25	105				±0.5, ±1	10 to 1M (E24, E96)										
ERJPA3	0.25	103	-	150	200	±5	1 to 1.5M (E24)	±0.5, ±1 : ±100									
(0603)	0.22		130		130	100	150	150	130	130	200	±0.5, ±1	10 to 1M (E24, E96)	±5 : ±200			
	0.33	-	130			±5	1 to 1.5M (E24)										
						±0.5	10 to 1M (E24, E96)	±150									
ERJP03 (0603)	0.20	70	-	-	-	-	-	-	-	_	150	200	±1	10 to 1M (E24, E96)	R<10Ω : –150 to +400	-55 to +155	
						±5	1 to 1M (E24)	10Ω≤R :±200									
ED IDOS										±0.5, ±1	10 to 1M (E24, E96)	R<33Ω :±300 33Ω≤R :±100		Grade 0			
ERJP06 (0805)	0.50	70	115	400	600	±5	1 to 3.3M (E24)	R<10Ω : −100 to +600 10Ω≤R<33Ω : ±300 33Ω≤R : ±200									
ERJP08	0.00	70	405	500	1000	±0.5, ±1	10 to 1M (E24, E96)	±100									
(1206)	0.66	70	125	500	1000	1000		R<10Ω : −100 to +600 10Ω≤R : ±200									
ERJPM8 (1206)	0.66	70	125	500	1000	±1	1.02M to 10M (E24, E96)	±100									
ERJP14	0.50	70			400	±0.5, ±1		±100									
(1210)			400	±5	1 to 1M (E24)	R<10Ω : −100 to +600 10Ω≤R : ±200											

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

<sup>\*2:</sup> If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

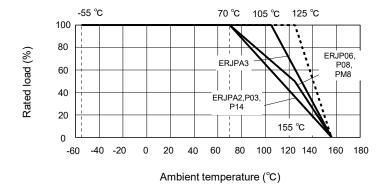
<sup>\*3:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

<sup>\*4:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

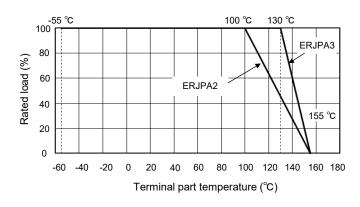
#### **Ratings**

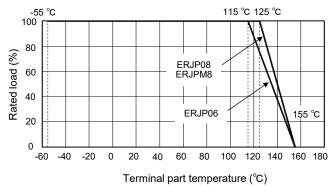
#### Power derating curve

- •For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.
  - In addition, please use under the condition that the product temperature is below the upper category temperature.
    - % When the temperature of ERJP14 is 155  $^{\circ}$ C or less, the derating start temperature can be changed to 125  $^{\circ}$ C. (See the dotted line)

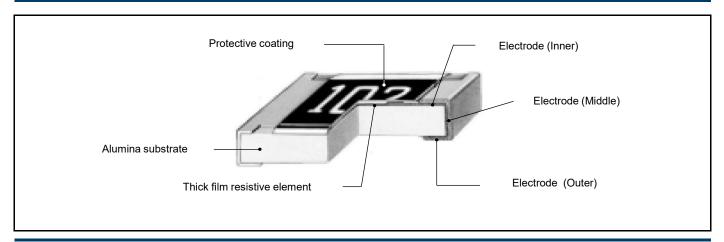


- •For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.
  - In addition, please use under the condition that the product temperature is below the upper category temperature.

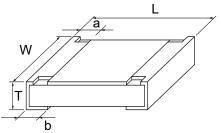




#### Construction



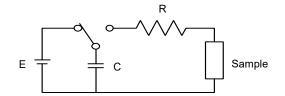
#### **Dimensions (not to scale)**



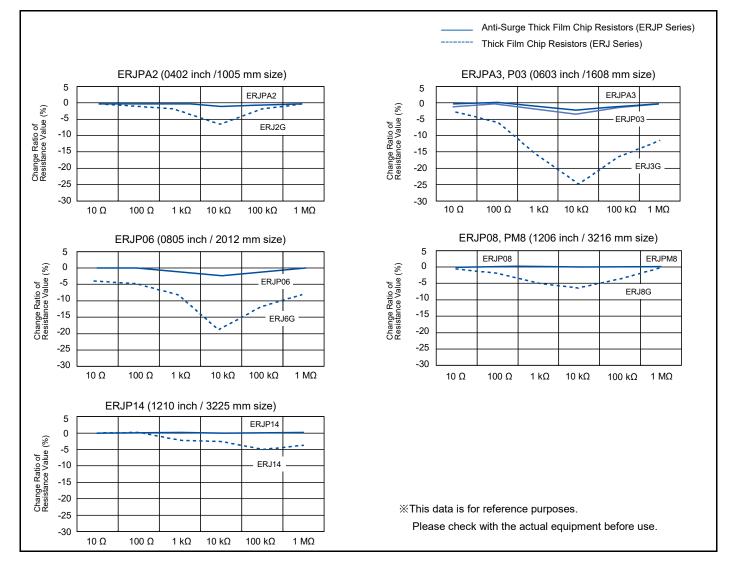
Unit: mm

Part No.	Dimensions								
Fait No.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERJPA2	1.00±0.05	0.50±0.05	0.20±0.15	0.25±0.10	0.35±0.05	0.8			
ERJPA3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJP03	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.30±0.15	0.45±0.10	2			
ERJP06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJP08,PM8	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			
ERJP14	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16			

# **ESD Characteristic**



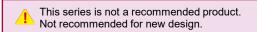
Size (inch)	0402	0603, 0805, 1206, 1210
R	1.5 kΩ	R=0 Ω ( $\leq$ 1.5 kΩ) / 150 Ω > 1.5 kΩ)
С	100 pF	150 pF
E	±1 kV	±3 kV



# **Anti-Surge Thick Film Chip Resistors**

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃ (ERJPA2 : +125 ℃)
	±2 %	ERJP06 : Rated voltag× 1.77, 5 s
Overload	Only when it is ERJP03 (D),	ERJPA2, ERJPA3, ERJP08, ERJPM8: Rated voltag× 2.0, 5 s
	P14 (D) : ±0.5 %	ERJP03, ERJP14 : Rated voltag× 2.5, 5 s
Resistance to soldering heat	D: ±0.5 %, F, J: ±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30min.) / +155 ℃ (ERJPA2 : +125 ℃) (30min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 % Only when it is ERJP03 (D), P14 (D) : ±1 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated ambient temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 % Only when it is ERJP03 (D), P14 (D) : ±1 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

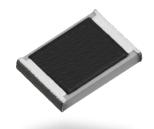




# Anti-Surge Thick Film Chip Resistors (Double-sided resistive elements structure)

ERJ P□W type

**ERJ P6W** series



#### **Features**

- ESD surge characteristics superior to standard metal film resistors
- Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power : 0.50 W, 2012(0805) size(ERJP6W)
- High pulse characteristics : 1.5 times higher than 0805 inch size Anti-Surge thick film chip

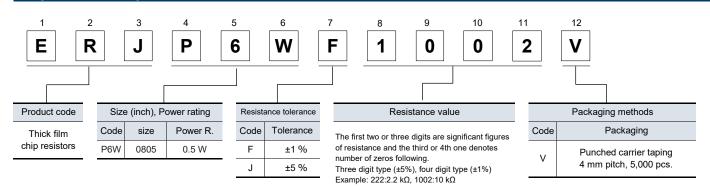
resistors (ERJP06)

Reference standards
 : IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B

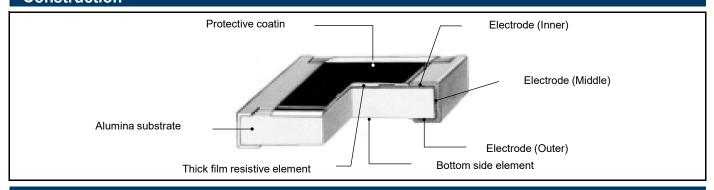
RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

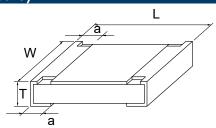
#### **Explanation of part numbers**



#### Construction



#### Dimensions in mm (not to scale)



Unit : mm

Туре			Mass (Weight)		
i yp <del>e</del>	L	W	а	Т	(g/1000 pcs)
ERJP6W (0805)	2.00±0.20	1.25±0.20	0.35±0.20	0.65±0.10	6

#### **Anti-Surge Thick Film Chip Resistors (Double-sided resistive elements structure)**

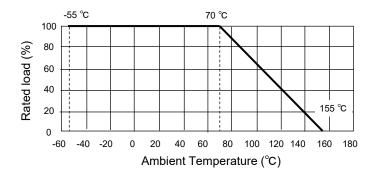
#### **Ratings**

Part No. (inch size)	Power rating <sup>*1</sup> (70 ℃) (W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup>	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (°C)	
ERJP6W	ERJP6W 0.5 1	150	200	± 1	10 to 1 M (E24,E96)	± 200	-55 to +155	
(0805)	0.5	150	200		1 to 1 M	R < 10 Ω : -100 to +600	-55 10 +155	
				± 5		10 Ω ≦ R : ±200	1	

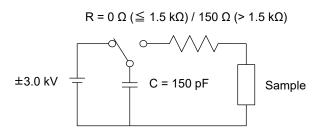
<sup>\*1:</sup> Use it on the condition that the case temperature is below 155  $^{\circ}$ C.

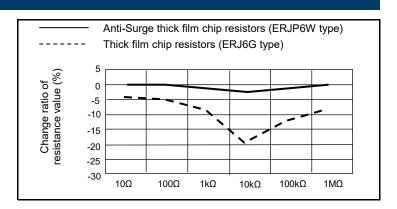
#### Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



#### **ESD Characteristic**





<sup>\*2:</sup> Overload (Short-time Overload) test voltage (SOTV) shall be determined from SOTV=2.5 × Power rating or max. Over load voltage listed above whichever less.

<sup>\*3:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

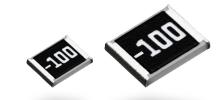
**INDUSTRY** 

# **Anti-Pulse Thick Film Chip Resistors**

ERJ T type

ERJ T06, T08, T14 series

**ERJ T14L** series

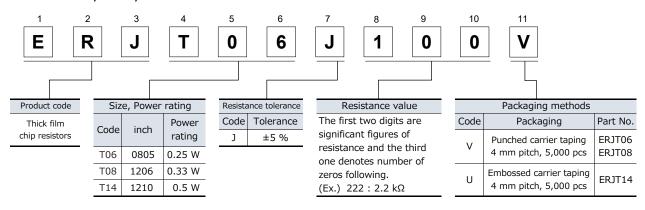


#### **Features**

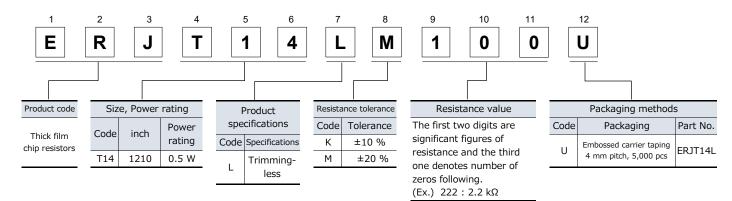
- Anti-Pulse characteristics
   High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)
- Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.25 W: 0805 inch /2012 mm size(ERJT06)
  - 0.33 W: 1206 inch /3216 mm size(ERJT08)
  - 0.50 W: 1210 inch /3225 mm size(ERJT14, ERJT14L)
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**

ERJT06, T08, T14 series



#### ERJT14L series



\* Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

#### **Anti-Pulse Thick Film Chip Resistors**

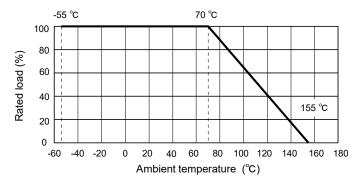
#### **Ratings**

Part No. (inch size)	Power rating <sup>*1</sup> (70 ℃)(W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M (E24)	R<10 Ω : $-100 \text{ to } +600$ 10 Ω≤R<33 Ω : $\pm 300$ 33 Ω≤R : $\pm 200$		
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R : ±200	-55 to +155	Grade 0
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M (E24)	R<10 $\Omega$ : -100 to +600 10 $\Omega \le R$ : ±200		
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M (E12)	R<10 Ω : -100 to +600 10 Ω≤R : ±200		

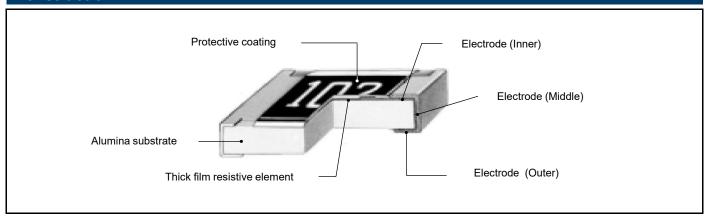
<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

#### **Power derating curve**

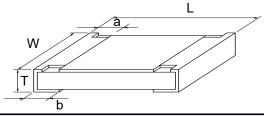
For resistors operated in ambient temperatures above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



#### Construction



#### **Dimensions (not to scale)**



Unit : mm

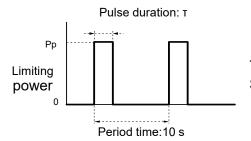
David Nia	Dimensions						
Part No.	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJT06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4	
ERJT08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10	
ERJT14 ERJT14L	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16	

<sup>\*2:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

#### **Limiting power curve**

• In rush pulse Characteristic

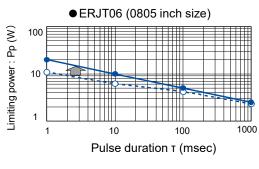


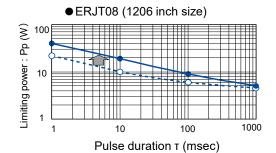
Test cycle: 1000 cycles

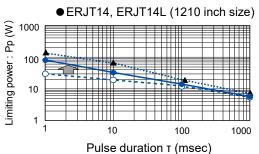
Spec : Resistance value = within ±5 %



 $\bigcirc$ : Thick Film Chip Resistors(Series ERJ : 1  $\Omega$ )







- %This data is for reference purposes.
  Please check with the actual equipment before use.
- ※ Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Periorillance		
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃±3 ℃, 10 s ±1 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃ ±2 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃ ±2 ℃, 90 % to 95 %RH, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70℃	±3 %	70 ℃ ±2 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

**INDUSTRY** 

# **Anti-Sulfurated Thick Film Chip Resistors**

ERJ S type (Au-based inner electrode type)

ERJ S02, S03, S06, S08, S14 series

ERJ S12, S1D, S1T series

ERJ U type (Ag-Pd-based inner electrode type)

ERJ U0X, U01, U02, U03, U06, U08, U14 series

ERJ U12. U1D. U1T. U6S. U6Q series

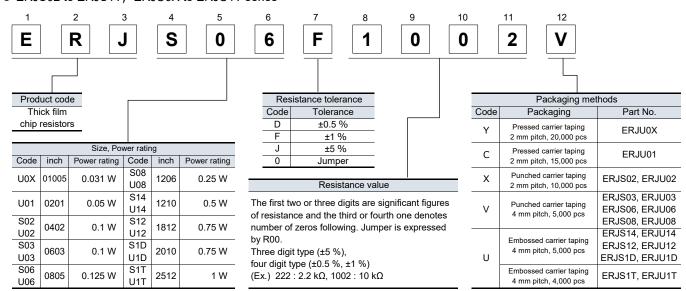


#### **Features**

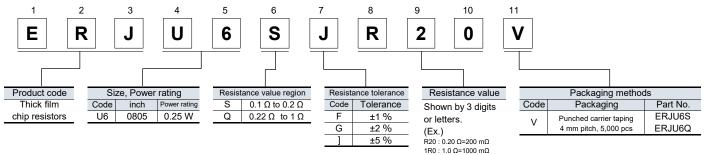
- High resistance to sulfurization achieved by adopting an Au-based inner electrode (Series ERJS) and Aq-Pd-based inner electrode (Series ERJU)
- : Metal glaze thick film resistive element and three layers of electrodes High reliability
- Suitable for both reflow and flow soldering
- : ERJU6S, U6Q series : 0.1  $\Omega$  to 1  $\Omega$ Low resistance type
- : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C Reference standard
- AEC-Q200 compliant (except ERJU0X, ERJU01)
- RoHS compliant
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**

• ERJS02 to ERJS1T, ERJU0X to ERJU1T series



ERJU6S, U6Q series



#### **Anti-Sulfurated Thick Film Chip Resistors**

Rating	S								
Part No. (inch size)	Power rating <sup>*1</sup> (70 ℃)(W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	Resistance tolerance (%)	raı	stance nge Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJU0X				±1	10 to 1 M	(E24, E96)	R<10 Ω : –100 to +600		
(01005)	0.031	15	30	Ξ.		(LZ4, L30)	10 Ω≤R<100 Ω : ±300		
<u> </u>				±5	1 to 1 M	(E24)	100 Ω≤R :±200	-55 to +125	-
ERJU01	0.05	25	50	±1	10 to 1 M	(E24, E96)	R<10 Ω : –100 to +600		
(0201)	0.00	20	00	±5	1 to 1 M	(E24)			
ERJS02				±0.5, ±1	1 to 1 M	(E24, E96)	10 Ω to 1 MΩ : ±200		
ERJU02 (0402)	0.1	50	100	±5	1 to 3.3 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJS03				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU03 (0603)	0.1	75	150	±5	1 to 10 M	(E24)			
ERJS06				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU06 (0805)	0.125	150	200	±5	1 to 10 M	(E24)			
ERJS08				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU08 (1206)	0.25	200	400	±5	1 to 10 M	(E24)	R<10 Ω : –100 to +600	551 .455	
ERJS14				±0.5, ±1	1 to 1 M	(E24, E96)	1 40 0 4 4 4 4 0 0 0 0 0 4 5 0 4 0	-55 to +155	Grade 0
ERJU14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	- 10 Ω to 1 MΩ : ±200 (± 5 %) : ±100 (±0.5 %, ±1 %)		
ERJS12				±0.5, ±1	1 to 1 M	(E24, E96)	(10.5 70, 11 70)		
ERJU12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJS1D				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU1D (2010)	0.75	200	500	±5	1 to 10 M	(E24)			
ERJS1T				±0.5, ±1	1 to 1 M	(E24, E96)	-		
ERJU1T (2512)	1.0	200	500	±5	1 to 10 M	(E24)			

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

#### [Low resistance type]

Part No. (inch size)	Power rating <sup>*1</sup> (70 ℃)(W)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJU6S (0805)	0.25	±1, ±2, ±5	0.1 to 0.2	(E24)	0 to +150	-55 to +155	Grade 0
ERJU6Q (0805)	0.25	±1, ±2, ±3	0.22 to 1	(E24)	0 10 +150	-55 10 + 155	Grade 0

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

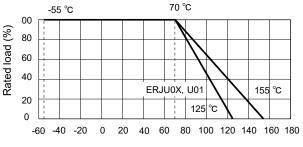
#### [For jumper]

ti oi juilipeij				
Part No.	Resistance	Rated current	Maximum overload current <sup>*1</sup>	
ERJU0X		0.5 A	1 A	
ERJU01		0.5 A		
ERJS02,ERJU02	- 100 mΩ or less	1 A	2 A	
ERJS03,ERJU03		IA	27	
ERJS06,ERJU06				
ERJS08,ERJU06	100 1112 01 1655			
ERJS14,ERJU14		2 A	4 A	
ERJS12,ERJU12		2.7	7.7	
ERJS1D,ERJU1D				
ERJS1T,ERJU1T				

<sup>\*1:</sup> Overload test current

#### Power derating curve

For resistors operated in ambient temperatures above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Ambient temperature (°C)

<sup>\*2:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

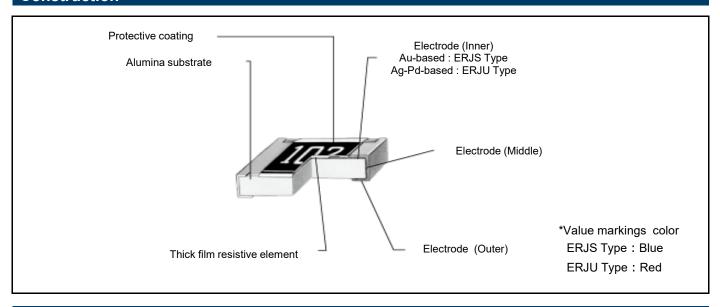
<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

<sup>•</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\( Power Rating \times Resistance Value. \)

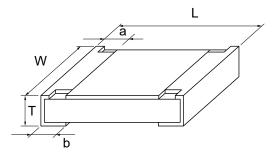
<sup>·</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

# **Anti-Sulfurated Thick Film Chip Resistors**

# Construction



# Dimensions (not to scale)



Unit: mm

Davi Na	Dimensions								
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERJU0X	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJU01	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJS02 ERJU02	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJS03 ERJU03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJS06 ERJU06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJU6□	2.00±0.20	1.25±0.10	0.45±0.20	0.45±0.20	0.55±0.10	6			
ERJS08 ERJU08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJS14 ERJU14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJS12 ERJU12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJS1D ERJU1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJS1T ERJU1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

# **Anti-Sulfurated Thick Film Chip Resistors**

# Performance

#### • ERJS02 to ERJS1T, ERJU0X to ERJU1T series

Test item	Performance re	equirements ⊿R	Test conditions
rest item	Resistor type	Jumper type	rest conditions
Resistance	Within specified tolerance	100 mΩ or less	20 ℃
T. C. R.	Within Specified T. C. R.	200 mΩ or less	+25 °C / +155 °C (ERJU0X,U01 : +25 °C / +125 °C)
Overload	±2 %	100 mΩ or less	Rated voltage × 2.5, 5 s Jumper type : Max. overload current, 5 s
Resistance to soldering heat	±1 %	100 mΩ or less	270 ℃, 10 s
Rapid change of temperature	±1 %	100 mΩ or less	–55 ℃ (30min.)/+155 ℃ (ERJU0X,U01 : +125 ℃) (30min.), 100 cycles
High temperature exposure	±1 %	100 mΩ or less	+155 ℃ (ERJU0X,U01 : +125 ℃), 1000 h
Damp heat, Steady state	±1 %	100 mΩ or less	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	100 mΩ or less	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	100 mΩ or less	70 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

#### • ERJU6S, U6Q series

Ertodo, dog sene	_	
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±1 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +125 ℃ (30min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

**INDUSTRY** 

# Anti-Sulfurated Thick Film Chip Resistors (Precision Type)



ERJ U□R type (Ag-Pd-based inner electrode type)

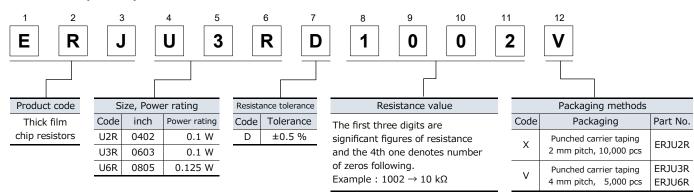
ERJ U2R, U3R, U6R series

#### **Features**

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode.
- ◆ High precision : Resistance tolerance : ±0.5 %, TCR : ±50 ×10<sup>-6</sup>/K
- High reliability : Metal glaze thick film resistive element and three layers of electrodes.
- Suitable for both reflow and flow soldering.
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**

#### ERJU2R, U3R, U6R series



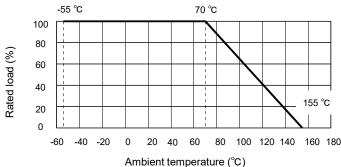
#### **Ratings**

Part No. (inch size)	Power rating*1 (70 ℃) (W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	Resistance tolerance (%)	Resistance range $(\Omega)$	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJU2R (0402)	0.1	50	100	±0.5	100 to 100 k (E24, E96)			
ERJU3R (0603)	0.1	75	150	±0.5	100 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
ERJU6R (0805)	0.125	150	200	±0.5	100 to 100 k (E24, E96)			

- \*1: Use it on the condition that the case temperature is below the upper category temperature.
- \*2 : Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.
- \*3 : Overload test voltage (OTV) shall be determined from OTV = Specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

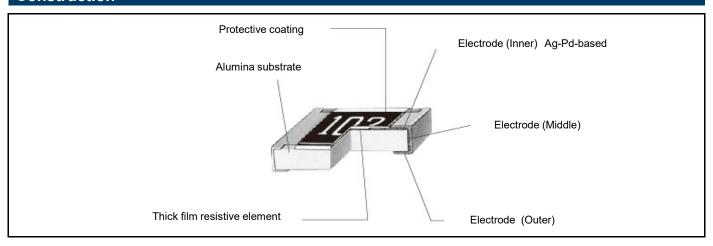
#### Power derating curve

For resistors operated in ambient temperatures above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.

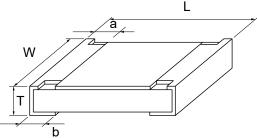


# **Anti-Sulfurated Thick Film Chip Resistors (Precsion Type)**

#### Construction



# **Dimensions (not to scale)**



Dimensions Mass (Weight) Part No. (Reference) W L b Τ (g/1000 pcs) 0.25±0.10 ERJU2R 1.00±0.05  $0.50 \pm 0.05$ 0.20±0.10 0.35±0.05 8.0 ERJU3R 1.60±0.15 0.80+0.15/-0.05 0.30±0.20 0.30±0.15 0.45±0.10 2 1.25±0.10 ERJU6R 2.00±0.20 0.40±0.20 0.40±0.20 0.60±0.10 4

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overload	±2 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±2 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

**INDUSTRY** 

# **Anti-Sulfurated Thick Film Chip Resistors** (Anti-Surge Type)

**ERJ UP type** 

ERJ UP3, UP6, UP8 series



#### **Features**

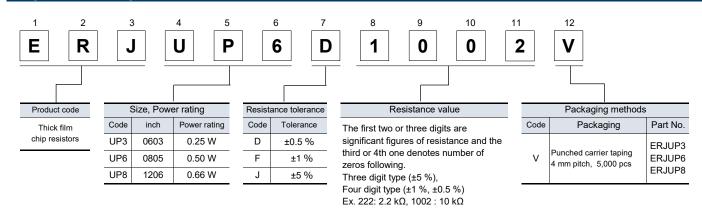
- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure
- ESD surge characteristics superior to standard metal film resistors
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power
   0.25 W: 0603 inch / 1608 mm size (ERJUP3)

0.50 W: 0805 inch / 2012 mm size (ERJUP6) 0.66 W: 1206 inch / 3216 mm size (ERJUP8)

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

- AEC-Q200 compliant
- RoHS compliant
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**



#### Ratings

Part No. (inch size)	Power rating*1 (70 ℃) (W)	Limiting element voltage*2 (V)	Maximum overload voltage*3 (V)	Resistance tolerance (%)	rar	stance nge Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (°C)	AEC-Q200 Grade
ERJUP3	0.25	150	200	±0.5, ±1	10 to 1 M	(E24, E96)	±100	-	
(0603)	0.23	150	200	±5	1 to 1.5 M	(E24)	±200		
ED 11.100				±0.5, ±1	10 to 1 M	(E24, E96)	±100		
ERJUP6 (0805)	0.50	400	600	±5	1 to 3.3 M	(E24)	R<10 Ω : –100 to +600	-55 to +155	Grade 0
(0000)	(0003)			10	1 to 3.3 W	(E24)	10 Ω≤R :±200	-55 10 +155	Grade 0
ED 11 100	55 W 150			±0.5, ±1	10 to 1 M	(E24, E96)	±100		
	ERJUP8 (1206) 0.66	500	1000		1 to 10 M	(E24)	R<10 Ω : –100 to +600		
(1200)				±5	1 to 10 M	(E24)	10 Ω≤R :±200		

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

<sup>\*2:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

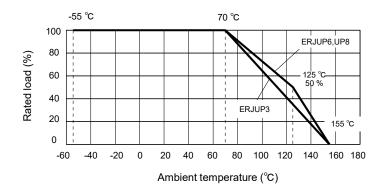
<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

# **Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)**

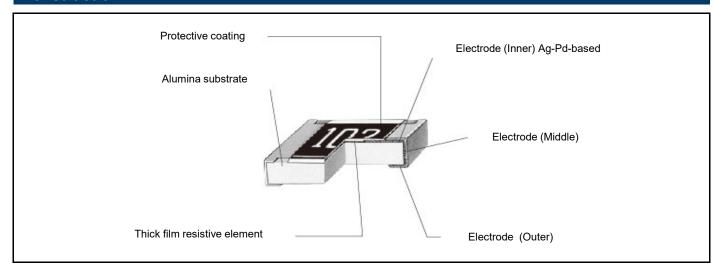
# Ratings

#### Power derating curve

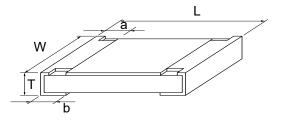
For resistors operated in ambient temperatures above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



# Construction



# Dimensions in mm (not to scale)

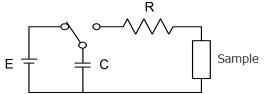


Unit : mm

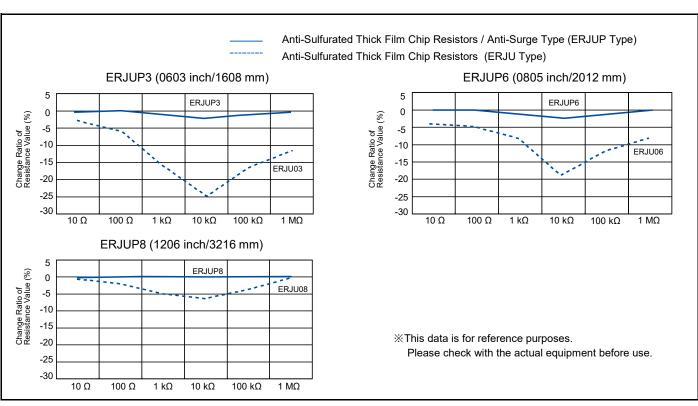
Part No.	Dimensions						
i ait ivo.	L	W	а	b	Т	(Reference) (g/1000 pcs)	
ERJUP3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2	
ERJUP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4	
ERJUP8	3.20+0.05/-0.20	1.6+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10	

# **Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)**

# **ESD Characteristic**



R	R=0 Ω( $\leq$ 1.5 kΩ) / 150 Ω( $>$ 1.5 kΩ)
С	150 pF
E	±3 kV



Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overland	12.0/	ERJUP6: Rated voltag x 1.77, 5 s
Overload	±2 %	ERJUP3, ERJUP8: Rated voltag x 2.0, 5 s
Resistance to soldering heat	D: ±0.5 % F, J: ±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

**INDUSTRY** 





ERJ C type
ERJ C1 series

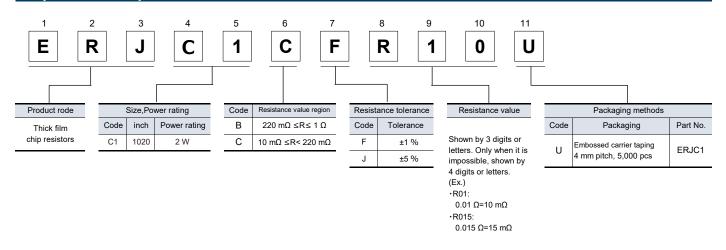
#### **Features**

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure (Covered electrode)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

#### **Recommended applications**

- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**



#### Ratings

Part No. (inch size)	Power rating <sup>*1</sup> (70 °C) (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJC1		±1	10 m to 1 (E24)	$10 \text{ m}\Omega \leq R < 22 \text{ m}\Omega : 0 \text{ to } +350$ $22 \text{ m}\Omega \leq R < 47 \text{ m}\Omega : 0 \text{ to } +200$ $47 \text{ m}\Omega \leq R < 100 \text{ m}\Omega : 0 \text{ to } +150$ $100 \text{ m}\Omega \leq R \leq 1 \Omega : \pm 100$	–55 to +155	Grade 0
(1020)		±5		$10 \text{ m}\Omega \le R < 22 \text{ m}\Omega : 0 \text{ to } +350$ $22 \text{ m}\Omega \le R < 100 \text{ m}\Omega : 0 \text{ to } +200$ $100 \text{ m}\Omega \le R \le 1 \Omega : \pm 200$		

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

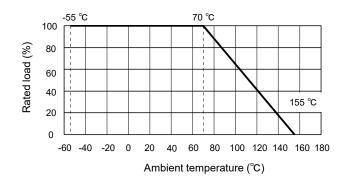
- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value.
- · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

# **Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)**

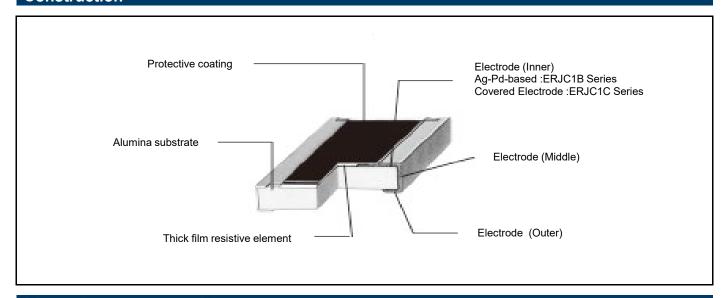
# Ratings

#### Power derating curve

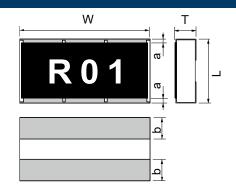
For resistors operated in ambient temperatures above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



#### Construction



#### **Dimensions (not to scale)**

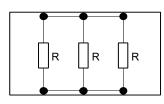


Unit : mm

Part No.	Dimensions  Part No.						
i aitino.	L W		а	b	Т	(Reference) (g/1000 pcs)	
ERJC1B	2.50±0.20	2.50±0.20 5.00±0.20		0.90±0.20	0.55±0.20	27	
ERJC1C	2.50±0.20	J.00±0.20	0.60±0.20	0.90±0.20	0.55±0.20	27	

#### **Circuit configuration**

ERJC1 series



# **Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)**

1 enomiance		
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage × 2.0, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±2 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

**INDUSTRY** 

# High Temperature Thick Film Chip Resistor (Automotive Grade)



1-Oct-20

**ERJH** type

ERJ H2G, H2C, H2R, H3G series

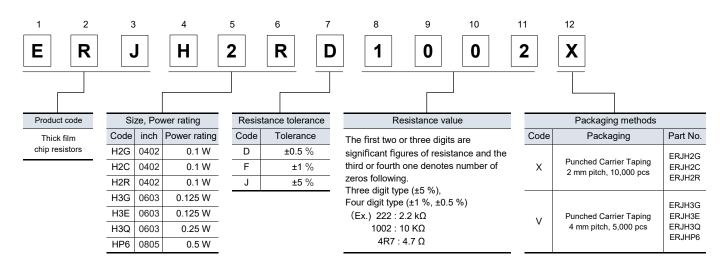
ERJ H3E, H3Q, H6G, HP6 series

#### **Features**

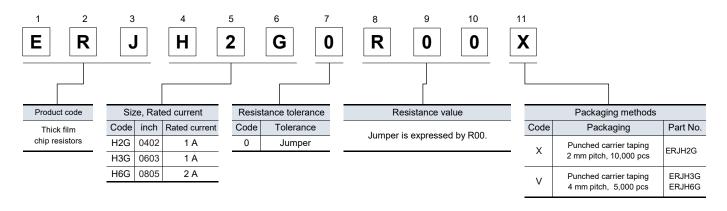
- High reliability : Metal glaze thick film resistive element and high temperature of electrodes structure
- Achieve maximum category temperature 175 ℃ and rated category temperature 105 ℃
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**

• ERJH2G, H2C, H2R, H3G, H3E, H3Q, HP6 series: ±0.5 %, ±1 %, ±5 %



ERJH2G, H3G, H6G series : Jumper



#### **High Temperature Thick Film Chip Resistor (Automotive Grade)**

#### **Ratings**

#### [For Resistor]

Part No. (inch size)	Power rating*1 (105 ℃) (W)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (°C)	AEC-Q200 Grade
ERJH2G (0402)	0.1	50	100	±5	1 to 300 k	(E24)	R < 10Ω : $-100$ to +600 10Ω ≤ R : $\pm 200$		
ERJH2C (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600		
ERJH2R (0402)	0.1	50	100	±0.5,±1	10 to 300 k	(E24,E96)	±100		
ERJH3G (0603)	0.125	75	150	±5	1 to 300 k	(E24)	R < $10\Omega$ : $-100$ to $+600$ $10\Omega \le R$ : $\pm 200$		
ERJH3E (0603)	0.125	75	150	±0.5,±1	10 to 300 k	(E24,E96)	±100	-55 to +175	Grade 0
ERJH3Q	0.25	_	_	±0.5,±1	1 to 9.76	(E24,E96)	±200	-55 10 + 175	Grade 0
(0603)	0.20			±5	1 to 9.1	(E24)			
	0.5	400	600	±0.5	10 to 300 k	(E24,E96)	R < 33Ω : ±300		
	0.0	100	000	20.0	10 to 000 K	(LL 1,L00)	$33\Omega \le R: \pm 100$		
							$R < 10\Omega : -100 \text{ to } +600$		
ERJHP6	0.5	400	600	±1	1 to 300 k	(E24,E96)	$10\Omega \le R < 33\Omega : \pm 300$		
(0805)							$33\Omega \le R: \pm 100$		
							$R < 10\Omega : -100 \text{ to } +600$		
	0.5	400	600	±5	1 to 300 k	(E24)	10Ω ≤R < 33Ω : ±300		
							$33\Omega \leq R : \pm 100$		

<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

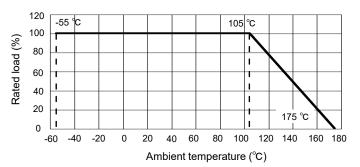
#### [For Jumper]

Part No. (inch size)	Resistance	Rated current	Maximum overload current*1
ERJH2G (0402)		1 A	2 A
ERJH3G (0603)	50 mΩ or less	1 A	2 A
ERJH6G (0805)		2 A	4 A

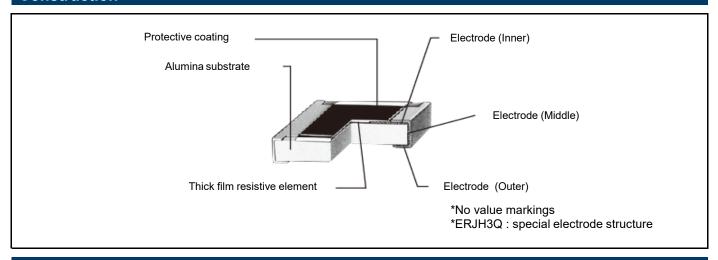
<sup>\*1:</sup> Overload test current

#### Power derating curve

For resistors operated in ambient temperatures above 105  $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



#### Construction

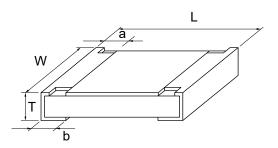


<sup>\*2:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

# **High Temperature Thick Film Chip Resistor (Automotive Grade)**

# Dimensions (not to scale)



Unit : mm

Part No.	Dimensions					
Fait No.	L	W	а	b	Т	(Reference) (g/1000 pcs)
ERJH2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8
ERJH2C	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8
ERJH2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	8.0
ERJH3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJH3E	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJH3Q	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJH6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4
ERJHP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4

Test item	Performance re	quirements ⊿R	Test conditions		
rest item	Resistor type	Jumper type	Test conditions		
Resistance	Within specified tolerance	50 mΩ or less	20 ℃		
T. C. R.	Within specified T. C. R.	50 mΩ or less	+25 ℃ / +175 ℃		
Overload	±2 %	50 mΩ or less	ERJH2G, H2C, H2R, H3G, H3E, H3Q : Rated voltage× 2.5, 5 s ERJHP6: Rated voltage× 1.77, 5 s Jumper type: Max. overload current, 5 s		
Resistance to soldering heat	±1 %	50 mΩ or less	270 ℃, 10 s		
Rapid change of temperature	±1 %	50 mΩ or less	–55 °C (30 min.) / +175 °C (30 min.), 1000 cycles		
High temperature exposure	±1 %	50 mΩ or less	+175 ℃, 1000 h		
Damp heat, Steady state	±1 %	50 mΩ or less	85 ℃, 85 %RH, 1000 h		
Load life in humidity	±3 %	50 mΩ or less	85 °C, 85 %RH, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 105 ℃	±3 %	50 mΩ or less	105 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		

**INDUSTRY** 

# **Chip Resistors Array**

EXB type

EXB 14V, 18V, 24V, 28V, N8V, 2HV, series

EXB 34V, V4V, 38V, V8V, S8V series



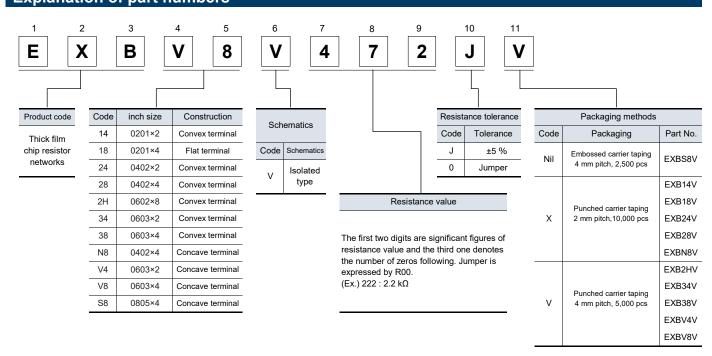
#### **Features**

- High density
  - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXB14V
  - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXB18V
  - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
  - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, N8V
  - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXB2HV
  - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, V4V
  - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXB38V, V8V
  - 4 resistors in 5.1 mm × 2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency

Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor

- : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129 Reference Standard
- AEC-Q200 compliant (EXB2, EXB3)
- RoHS compliant
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**



#### Ratings

#### [For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage <sup>*1</sup> (V)	Maximum overload voltage <sup>*2</sup> (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (°C)	AEC-Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)			
EXB18V (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)			-
EXB24V (0402×2)	0.063	50	100	±5	1 to 1 M (E24)			
EXB28V (0402×4)	0.063	50	100	±5	1 to 1 M (E24)			
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	R<10 Ω		Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1 M (E24)	: –200 to +600 10 Ω to 1 MΩ	-55 to +125	
EXB38V (0603×4)	0.063	50	100	±5	1 to 1 M (E24)	: ±200		
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1 M (E24)			
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1 M (E24)			
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1 M (E24)			-
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1 M (E24)			

<sup>\*1:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

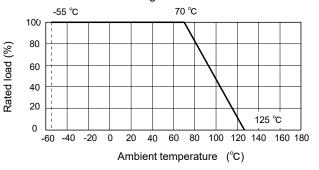
#### [For Jumper]

Part No.	Resistance	Rated current	Maximum overload current <sup>*1</sup>
EXB14V		0.5 A	1 A
EXB18V		0.5 A	1 A
EXB24V		1 A	2 A
EXB28V	50 mΩ or less	1 A	2 A
EXB2HV		1 A	2 A
EXB34V		1 A	2 A
EXB38V		1 A	2 A
EXBN8V		1 A	2 A
EXBV4V		1 A	2 A
EXBV8V		1 A	2 A
EXBS8V		2 A	4 A

<sup>\*1:</sup> Overload test current

#### Power derating curve

For resistors operated in ambient temperatures above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure below.

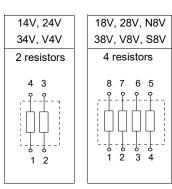


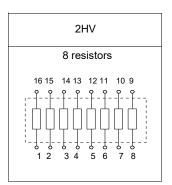
#### **Construction** (Example : Concave terminal)

# Protective coating Alumina substrate Electrode (Outer) Thick film Electrode (Between) resistive element Electrode (Inner)

### **Schematics**

#### ● Isolated type



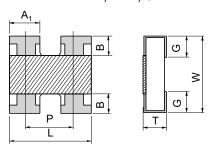


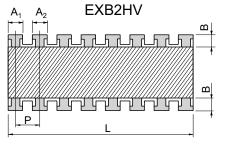
<sup>\*2:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

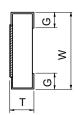
# **Dimensions (not to scale)**

#### (1) Convex terminal type

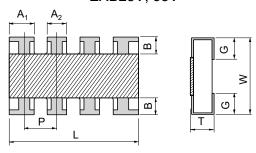
EXB14V, 24V, 34V







EXB28V, 38V



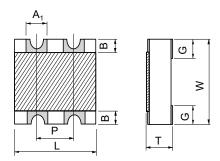
Unit:mm

Part No.	Dimensions								
(inch size)	L	W	Т	A <sub>1</sub>	$A_2$	В	Р	G	(Reference) (g/1000 pcs)
EXB14V (0201×2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXB24V (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXB28V (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXB2HV (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXB34V (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXB38V (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

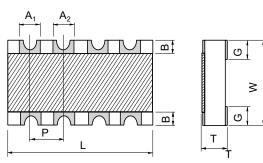
() Reference

#### (2) Concave terminal type

EXBV4V



#### EXBN8V, V8V, S8V



Unit : mm

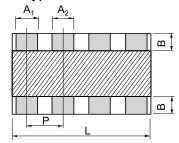
Part No.	Dimensions							Mass (Weight) (Reference)	
(inch size)	L	W	Т	A <sub>1</sub>	$A_2$	В	Р	G	(g/1000 pcs)
EXBN8V (0402×4)	2.00±0.10	1.00±0.10	0.45±0.10	0.30±0.10	0.30±0.10	0.20±0.15	(0.50)	0.30±0.15	3.0
EXBV4V (0603×2)	1.60 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	_	0.30±0.15	(0.80)	0.45±0.15	5.0
EXBV8V (0603×4)	3.20 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	0.60±0.10	0.30±0.15	(0.80)	0.45±0.15	10
EXBS8V (0805×4)	5.08 +0.20/-0.10	2.20 +0.20/-0.10	0.70±0.20	0.80±0.15	0.80±0.15	0.50±0.15	(1.27)	0.55±0.15	30

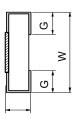
() Reference

# Dimensions (not to scale)

# (3) Flat terminal type

EXB18V





Unit : mm

Part No.	Dimensions							Mass (Weight) (Reference)	
(inch size)	L	W	Т	$A_1$	$A_2$	В	Р	G	(g/1000 pcs)
EXB18V (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0

() Reference

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage x 2.5, 5 s  Jumper type : Max. overload current, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

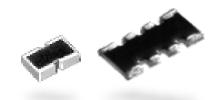
**INDUSTRY** 

# **Anti-Sulfurated Chip Resistors Array**

**EXB** type

EXB 14V, 18V, 24V, 28V, N8V, 2HV series

**EXB 34V, V4V, 38V, V8V, S8V** series



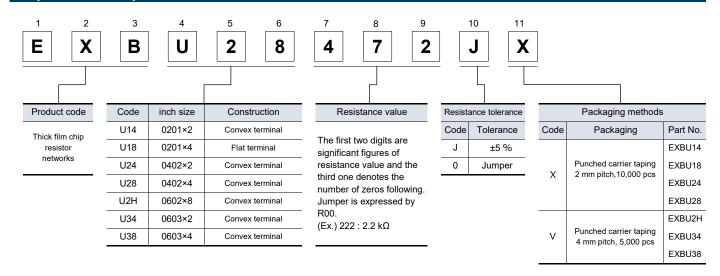
#### **Features**

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density
  - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXBU14
  - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXBU18
  - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXBU24
  - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28
  - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXBU2H
  - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34
  - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXBU38
- Improvement of placement efficiency

Placement efficiency of chip resistor array is two, four or eight times of the flat type chip resistor

- Reference standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXBU2, EXBU3)
- RoHS compliant
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

#### **Explanation of part numbers**



# Ratings

#### [For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage <sup>*1</sup> (V)	Maximum overload voltage <sup>*2</sup> (V)	Resistance tolerance (%)	Resistar range (Ω)		T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (°C)	AEC-Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1 M	(E24)			_
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M	(E24)			-
EXBU24 (0402×2)	0.063	50	100	±5	1 to 1 M	(E24)	R<10 $\Omega$ : -200 to +600 10 $\Omega$ to 1 M $\Omega$ : ±200	-55 to +125	
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1 M	(E24)			
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M	(E24)			Grade 1
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1 M	(E24)			
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1 M	(E24)			

<sup>\*1:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating x Resistance Value, or Limiting Element Voltage listed above, whichever less.

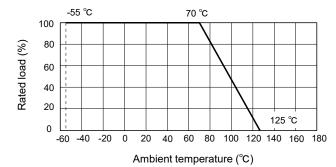
#### [For Jumper]

Part No.	Resistance	Rated current	Maximum overload current <sup>*1</sup>
EXBU24			
EXBU28			
EXBU2H	100 mΩ or less	1 A	2 A
EXBU34			
EXBU38			

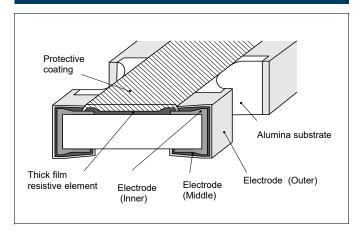
<sup>\*1:</sup> Overload test current

#### Power derating curve

For resistors operated in ambient temperatures above 70℃, power rating shall be derated in accordance with the figure below.

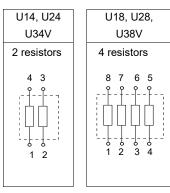


#### Construction



# **Schematics**

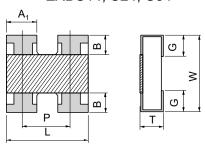
#### ● Isolated type



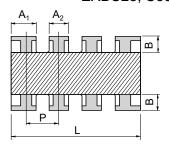
<sup>\*2:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

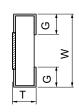
# Dimensions (not to scale)

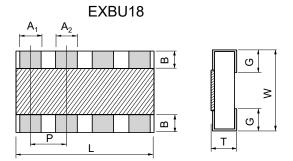
EXBU14, U24, U34

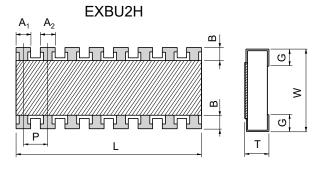


**EXBU28, U38** 









Unit : mm

Part No.		Dimensions										
(inch size)	L	W	Т	A <sub>1</sub>	$A_2$	В	Р	G	(Reference) (g/1000 pcs)			
EXBU14 (0201X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5			
EXBU18 (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0			
EXBU24 (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2			
EXBU28 (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0			
EXBU2H (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0			
EXBU34 (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5			
EXBU38 (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0			

() Reference

### Performance

1 enomiance		
Test Item	Performance	Test conditions
	requirements ⊿R	
Resistance	Within specified	20 ℃
	tolerance	
T. C. R.	Within Specified	+25 ℃ / +125 ℃
1. 0. 10.	T. C. R.	
Overload	±2 %	Rated voltage x 2.5, 5 s
Overload	12 /0	Jumper type : Max. overload current, 5 s
Resistance to	±1 %	270 ℃, 10 s
soldering heat	±1 70	270 C, 10 S
Rapid change of	±1 %	FF %C (20 main ) / 142F %C (20 main ) 400 avalor
temperature	±1 70	$-55$ $^{\circ}$ C (30 min.) / +125 $^{\circ}$ C (30 min.), 100 cycles
High temperature	±1 %	1405 °C 4000 h
exposure	±1 70	+125 ℃, 1000 h
Damp heat,	14.0/	00 %C 00 0/ +- 05 0/ DLL 4000 I
Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
-		60 ℃, 90 % to 95 %RH, Rated voltage
Load life in humidity	±3 %	(Jumper type : Rated current),
·		1.5 h ON / 0.5 h OFF cycle, 1000 h
		70℃, Rated voltage (Jumper type : Rated current),
Endurance at 70℃	±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
	1	1.0 11 014 / 0.0 11 011 01010, 1000 11

# **Panasonic**

**INDUSTRY** 

# **Chip Resistors Networks**

EXB type

EXB D, E, A, Q series



#### **Features**

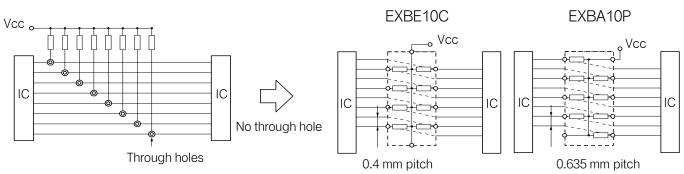
- High density placing for digital signal circuits
  - ·Bussed 8 or 15 resistors for pull up/down circuits

EXBD :  $3.2 \text{ mm} \times 1.6 \text{ mm} \times 0.55 \text{ mm}$ , 0.635 mm pitch EXBE :  $4.0 \text{ mm} \times 2.1 \text{ mm} \times 0.55 \text{ mm}$ , 0.8 mm pitch EXBA :  $6.4 \text{ mm} \times 3.1 \text{ mm} \times 0.55 \text{ mm}$ , 1.27 mm pitch EXBQ :  $3.8 \text{ mm} \times 1.6 \text{ mm} \times 0.45 \text{ mm}$ , 0.5 mm pitch

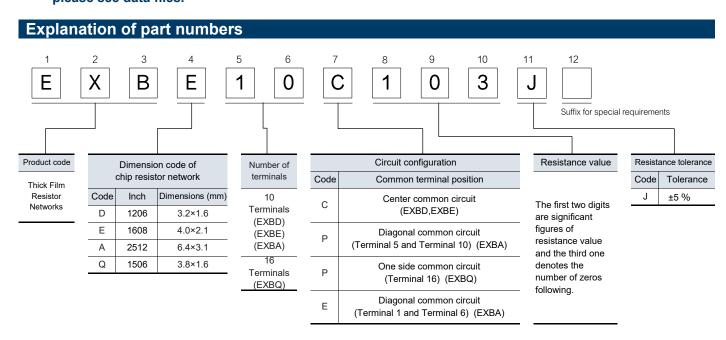
- Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine
- Reference Standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2130
- RoHS compliant

### [ High density placing ]

Pull up resistors Direct placement on the bus line



■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.



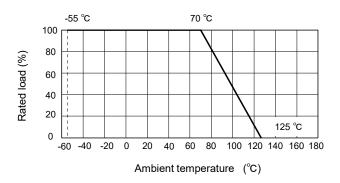
### **Ratings**

Part No. (inch size)	Resistance range (Ω)	Resistance tolerance (%)	Number of terminals	Number of resistors	Power rating <sup>*1</sup> (70 °C) (W/element)	Limiting element voltage <sup>*2</sup> (V)	Maximum overload voltage <sup>*3</sup> (V)	T.C.R. (×10 <sup>-6</sup> /K)	Category temperature range (℃)	AEC-Q200 Grade
EXBD (1206)					0.05 / element	25	50	±200		
EXBE (1608)	47 to 1 M (E12)	±5	10 terminals	8 element	0.063 / element	25	50	±200	55 to +125	-
EXBA (2512)	±5	13			0.063 / element	50	100	±200		
EXBQ (1506)	100 to 470 k (E6)		16 terminals	15 element	0.025 / element	25	50	±200		

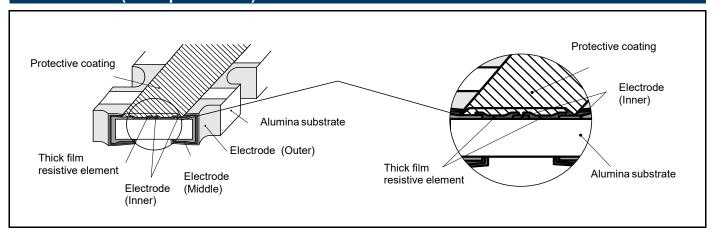
<sup>\*1:</sup> Use it on the condition that the case temperature is below the upper category temperature.

#### Power derating curve

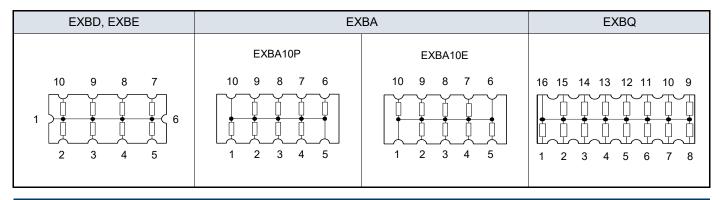
For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.



## **Construction (Example: EXBD)**



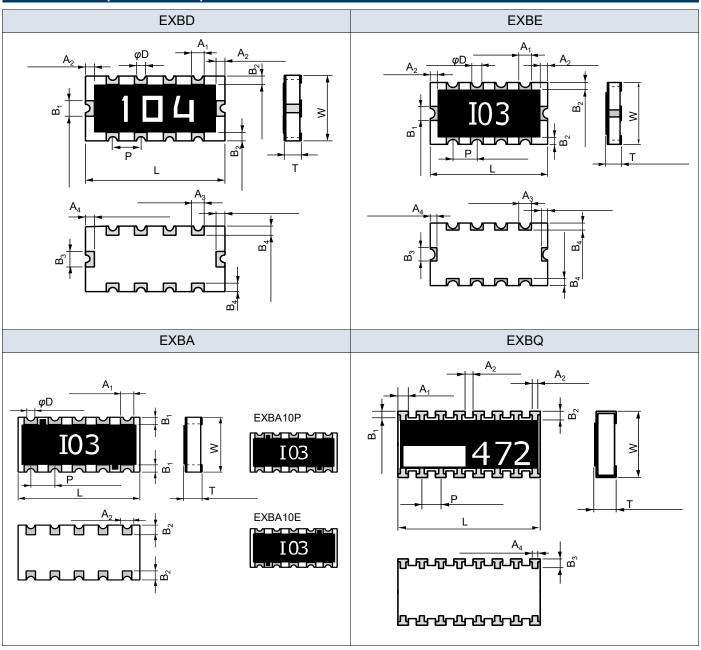
## **Circuit configuration**



<sup>\*2:</sup> Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

<sup>\*3:</sup> Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

# Dimensions (not to scale)



1.1 14	
Unit	 m

								Unit : mm Mass (Weight)				
Part No.	Dimensions											
i ait ivo.	L	W	T	A <sub>1</sub>	$A_2$	B <sub>1</sub>	B <sub>2</sub>	(Reference) (g/1000 pcs)				
	3.20±0.15	1.60±0.15	0.55±0.10	0.33±0.15	0.2±0.1	0.40±0.15	0.2±0.1					
EXBD	$A_3$	$A_4$	B <sub>3</sub>	B <sub>4</sub>	Р	ø D		10				
	0.3±0.1	0.25±0.10	0.40±0.15	0.35±0.15	0.635±0.10	0.2±0.1						
				Dimensions				Mass (Weight)				
Part No.	L	W	Т	A <sub>1</sub>	$A_2$	B <sub>1</sub>	B <sub>2</sub>	(Reference) (g/1000 pcs)				
	4.0±0.2	2.1±0.2	0.55±0.10	0.5±0.2	0.3±0.2	0.5±0.2	0.25±0.20					
EXBE	$A_3$	$A_4$	B <sub>3</sub>	B <sub>4</sub>	Р	øD		16				
•	0.4±0.2	0.35±0.20	0.5±0.2	0.4±0.2	0.8±0.1	0.3+0.1/-0.2						
David Na	Dimensions											
Part No.	L	W	Т	A <sub>1</sub>	B <sub>1</sub>	A <sub>2</sub>	B <sub>2</sub>	(Reference) (g/1000 pcs)				
	6.4±0.2	3.1±0.2	0.55±0.10	0.7±0.2	0.3±0.2	0.5±0.2	0.5±0.20					
EXBA	Р	øD						40				
	1.27±0.10	0.3+0.1/-0.2										
Dort No		Dimensions										
Part No.	L	W	T	A <sub>1</sub>	A <sub>2</sub>	$A_3$	B <sub>1</sub>	(Reference) (g/1000 pcs)				
EXBQ	3.8±0.2	1.6±0.2	0.45±0.10	0.3±0.1	0.2±0.1	0.15+0.15/-0.05	0.15+0.15/-0.05					
		۸	$B_3$	Р				9				
EXBQ	$B_2$	$A_4$	D <sub>3</sub>					9				

# **Chip Resistors Networks**

# Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±3 %	Rated voltage x 2.5, 5 s
Resistance to soldering heat	±1 %	260 ℃ ±5 ℃, 5 s ±1 s
Rapid change of temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 5 cycles
High temperature exposure	±3 %	+125 ℃, 100 h
Load life in humidity	±3 %	60 ℃±2 ℃, 90 % to 95 %RH, Rated power × 0.1, 1.5 h ON / 0.5 h OFF cycle, 500 h
Endurance at 70 ℃	±5 %	70 ℃±2 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

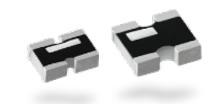
# **Panasonic**

INDUSTRY

# **Chip Attenuator**

# EXB type

# EXB 14AT, 24AT series



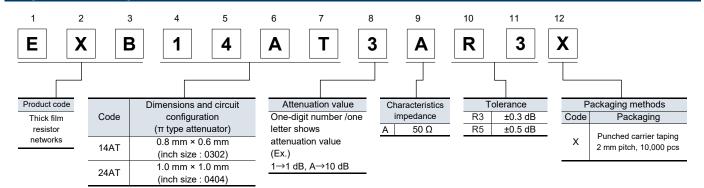
#### **Features**

- Unbalanced π type attenuator circuit in one chip EXB14AT (0.8 mm×0.6 mm), EXB24AT (1.0 mm×1.0 mm)
- Reduced mounting area
  - EXB14AT : About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors
  - EXB24AT : About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors
- Mounting cost reduction: (Only 1 chip placed as compared to 3)
- Attenuation: 1 dB to 10 dB
- RoHS compliant

### **Recommended applications**

- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
  - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

# **Explanation of part numbers**

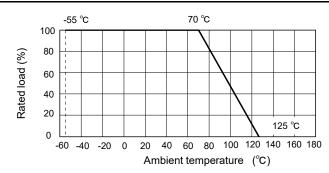


Ratings	
Part No.	EXB14AT, EXB24AT
Attenuation value	1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB*
Attenuation value tolerance	1 dB, 2 dB, 3 dB, 4 dB, 5dB: ±0.3 dB
Attenuation value tolerance	6 dB, 10 dB: ±0.5 dB
Characteristic impedance	50 Ω
Power rating at 70 ℃	0.04 W / package
Frequency range	DC to 3.0 GHz
VSWR (Voltage standing wave ratio)	1.3 max.
Number of resistors	3 resistors
Number of terminals	4 terminals
Category temperature range	–55 ℃ to +125 ℃

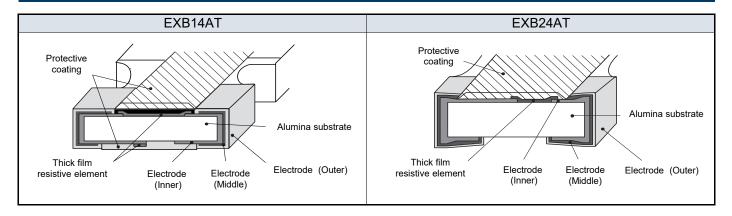
\* Please inquire about the other Attenuator value

#### Power derating curve

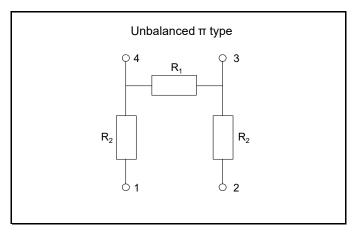
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



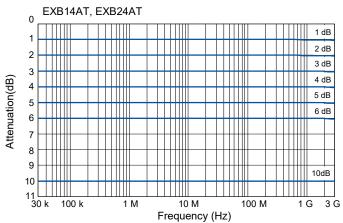
## Construction



# **Circuit configuration**

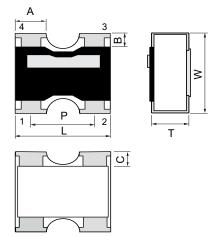


# **Attenuation-frequency characteristics**



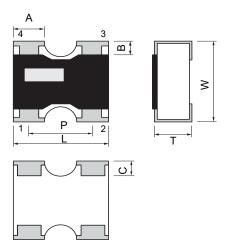
# Dimensions (not to scale)





< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 3, 4.

### EXB24AT



< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 4.

								Unit: mm				
Part No.	Dimensions											
		1.00	_		_		D (	(Reference)				
	L	W	l l	A	В	C	P (typical value)	(g/1000 pcs)				
EXB14AT	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	0.15±0.10	0.15±0.10	0.50	0.7				
EXB24AT	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	0.15±0.10	0.25±0.10	0.65	1.1				

Surfac	ce mount resistors series	3		Packaging (Standard	d quantity : pcs/reel)	
		0:	Pressed	Punched	Punched	Embossed
Products	Part No.	Size	carrier taping	carrier taping	carrier taping	carrier taping
		(mm) (inch)	(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)
	ERJXGN	0402 (01005)	20,000*1	_	_	40,000*2
	ERJ1GN	0603 (0201)	15,000	_	_	
	ERJ2GE	1005 (0402)	_	10,000	_	_
	ERJ3GE	1608 (0603)	_	_	5,000	_
Thick film	ERJ6GE	2012 (0805)	_	_	5,000	_
chip resistors	ERJ8GE	3216 (1206)		_	5,000	_
<b>-</b>	ERJ14	3225 (1210)			— — — — — — — — — — — — — — — — — — —	5,000
	ERJ12	4532 (1812)				5,000
	ERJ12Z	5025 (2010)	<u> </u>	_		5,000
	ERJ1T	6432 (2512)				4,000
	ERJXGN	0402 (01005)			<u> </u>	
	ERJ1GN/1RH	0603 (0201)	20,000 <sup>*1</sup> 15,000	_	<u> </u>	40,000 <sup>*2</sup>
	ERJ2RC/2RH/2RK	1005 (0402)	•	10,000	<u> </u>	_
		. ,	_	10,000		_
Precision	ERJ3RB/3RE/3EK ERJ6RB/6RE/6EN	1608 (0603)	_	_	5,000	_
thick film		2012 (0805)	_	_	5,000	_
chip resistors	ERJ8EN	3216 (1206)	_	_	5,000	_
	ERJ14N	3225 (1210)	<del>-</del>	<del>-</del>	<del>-</del>	5,000
	ERJ12N	4532 (1812)	_	_	_	5,000
	ERJ12S	5025 (2010)	_	_	_	5,000
	ERJ1TN	6432 (2512)	_	_		4,000
Market Closs	ERA1A	0603 (0201)	15,000	_	_	_
Metal film (Thin film)	ERA2A/2V	1005 (0402)	_	10,000	_	_
chip resistors,	ERA3A/3V/3K	1608 (0603)	_	_	5,000	_
High reliability type	ERA6A/6V/6K	2012 (0805)	_	_	5,000	_
, , , ,	ERA8A/8V/8K/8P	3216 (1206)	_		5,000	_
	ERJ2LW/2BW	1005 (0402)	10,000		_	_
	ERJ2BS/2BQ	1005 (0402)		10,000		_
	ERJ3L/3B/3R/L03	1608 (0603)	_	_	5,000	_
Thick film	ERJ2LW/2BW 1005 (0402) 10,000 ERJ2BS/2BQ 1005 (0402) — ERJ3L/3B/3R/L03 1608 (0603) — ERJ6L/6B/6C 2012 (0805) —	_	_	5,000	_	
chip resistors/	ERJ8B/8C/8R/L08	3216 (1206)			5,000	
Low resistance type	ERJ14B/14R/L14	3225 (1210)				5,000
,,	ERJ12R/L12	4532 (1812)				5,000
	ERJ12Z/L1D	5025 (2010)				5,000
	ERJ1TR	6432 (2512)		_		4,000
	ERJL1W	6432 (2512)				3,000
	ERJMP2	3216 (1206)	<del></del>	_	<del>_</del>	3,000
	ERJMP3	5025 (2010)	<u>—</u>	_	<u> </u>	3,000
		6432 (2512)	<u>—</u>	_	<u> </u>	·
Current sensing	ERJMP4 ERJMS4	, ,	<del>_</del>	_	<del>_</del>	2,000
resistors,	ERJIVI54	6432 (2512)	_	_	<u> </u>	2,000
Metal plate type	ERJMS6	6468 (2526)	_	_	_	1,000 (8mm Pitch)
	ERJMB1	2550 (1020)	_	_	_	3,000
	ERJM1W	6432 (2512)	_	_	_	3,000
Current sensing resistors, Metal foil type	ERJMFBA	1005 (0402)	_	10,000	_	_
	ERJA1	3264 (1225)	_	_	_	4,000
High power chip resistors/	ERJB1/ERJC1*3 ERJD1*4	2550 (1020)	_	_	_	5,000
Wide terminal type	ERJB2/ERJD2*4	1632 (0612)	_	_	5,000	_
	ERJB3	1220 (0508)	_	_	5,000	_
				1		l .

<sup>\*1:</sup> W8P2 : Width 8 mm, Pitch 2 mm,

<sup>\*2:</sup> W4P1 : Width 4 mm, Pitch 1 mm

<sup>\*3:</sup> Anti-Sulfurated High power chip resistors / Wide terminal type

<sup>\*4:</sup> Low TCR High power chip Resistors / Wide terminal type

Surface	e mount resistors serie	es		Packaging (Standar	· · · · · · · · · · · · · · · · · · ·	
		Size	Pressed	Punched	Punched	Embossed
Products	Part No.	(mm) (inch)	carrier taping	carrier taping	carrier taping	carrier taping
		, , , ,	(2 mm pitch)	(2 mm pitch )	(4 mm pitch)	(4 mm pitch)
High precision thick	ERJPB3	1608 (0603)	_	_	5,000	_
film chip resistors	ERJPB6	2012 (0805)	_	_	5,000	_
	ERJPA2	1005 (0402)	_	10,000	_	_
North Common This of files	ERJP03/PA3	1608 (0603)	_	_	5,000	_
Anti-Surge Thick film chip resistors	ERJP06	2012 (0805)	_	_	5,000	_
Criip resistors	ERJP08/PM8	3216 (1206)	_	_	5,000	_
	ERJP14	3225 (1210)	_	_	_	5,000
	ERJT06	2012 (0805)	_	_	5,000	_
Anti-Pulse Thick	ERJT08	3216 (1206)	_	_	5,000	_
film chip resistors	ERJT14	3225 (1210)	_	_	_	5,000
	ERJU0X	0402 (01005)	20,000	_	_	
	ERJU01	0603 (0201)	15,000	_	_	_
	ERJS02/U02	1005 (0402)		10,000		_
	ERJS03/U03	1608 (0603)			5,000	
	ERJS06/U06	1000 (0000)			0,000	
Anti-Sulfurated Thick film	ERJU6S/U6Q	2012 (0805)	_	_	5,000	
chip resistors	ERJS08/U08	3216 (1206)	_		5,000	_
	ERJS14/U14	3225 (1210)	_	_	_	5,000
	ERJS12/U12	4532 (1812)	_	_	_	5,000
	ERJS1D/U1D	5025 (2010)	_	_	_	5,000
	ERJS1T/U1T	6432 (2512)	_	_	_	4,000
Anti-Sulfurated	ERJU2R	1005 (0402)	_	10,000	_	<del>_</del>
Thick film chip	ERJU3R	1608 (0603)		, 	5,000	
resistors / Precision type		, ,			· · · · · · · · · · · · · · · · · · ·	
Precision type	ERJU6R	2012 (0805)	_	_	<u> </u>	_
Anti-Sulfurated Thick film chip resistors /	ERJUP3	1608 (0603)	_	_	5,000	_
	ERJUP6	2012 (0805)	_	_	5,000	_
Anti-Surge type	ERJUP8	3216 (1206)	_	- 5,000 10,000 - 5,000	_	
	ERJH2G/2C/2R	1005 (0402)	_	10,000	_	_
High temperature thick	ERJH3G/3E/3Q	1608 (0603)	_	_	5,000	_
film chip resistor	ERJH6G/HP6	2012 (0805)	_	_	5,000	_
	EXB14V	0806 (0302)	_	10,000	_	_
	EXB24V	1010 (0404)	_	10,000	_	_
	EXB34V	1616 (0606)		_	5,000	
	EXBV4V	1616 (0606)			5,000	
	EXB18V	1406 (0502)	<u> </u>	10,000	<u> </u>	
Chip resistor	EXB28V	2010 (0804)		10,000	_	<u> </u>
array	EXBN8V	2010 (0804)	_		_	
			_	10,000	<u> </u>	_
	EXB38V	3216 (1206)		_	5,000	
	EXBV8V	3216 (1206)		_	5,000	
	EXBS8V	5022 (2009)	_	_		2,500
	EXB2HV	3816 (1506)	_	_	5,000	_
_	EXBU14	0806 (0302)	_	10,000	_	_
	EXBU18	1406 (0502)	_	10,000	_	_
Anti-Sulfurated	EXBU24	1010 (0404)	_	10,000	_	_
chip resistor array	EXBU34	1616 (0606)	_	_	5,000	
p : : - : - : - : - : - : - : - : -	EXBU28	2010 (0804)	_	10,000	_	_
	EXBU38	3216 (1206)	_	_	5,000	_
	EXBU2H	3816 (1506)	_	_	5,000	_
	EXBD	3216 (1206)	_	_	5,000	_
	EXBE	4021 (1608)	_	_	<u> </u>	4,000
hip resistor networks	EXBA	6431 (2512)	_	_	_	4,000
	EXBQ	3816 (1506)	_	_	5,000	
	EXB14AT	0806 (0302)	_	10,000		
Chip attenuator	EXB24AT	1010 (0404)		10,000		

øD<sub>1</sub> (Only Emboss)



#### Carrier tape Pressed Punched Embossed carrier carrier carrier $\phi D_0$ Щ ≥ 1 <u>m</u> 0 Т Т A (2 mm pitch)

Pressed	carrier t	aping (2	? mm Pi	tch)								
● Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / Anti-Sulfurated												
Part No.	Size (inch)	Α	В	W	F	Е	P <sub>1</sub>	P <sub>2</sub>	P <sub>0</sub>	$\phi D_0$	Т	
ERJXGN ERJU0X	0402 (01005)	0.24±0.03	0.45±0.03								0.31±0.05	
ERJ1GN ERJ1R□ ERJU01 ERA1A	0603 (0201)	0.38±0.05	0.68±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.42±0.05	
ERJ2LW	1005 (0402)	0.68±0.10	1.20±0.10								0.60±0.05	
ERJ2BW	1111 (0.02)	0.67±0.10	1.17±0.10								0.61±0.05	

Punched	d carrier t	tapıng (	2 mm P	itch)							
Chip resistors / Precision chip / Thin film chip / Low resistance / Anti-Surge / Anti-Sulfur / High temperature / Metal foil type											
Part No.	Size (inch)	Α	В	W	F	Е	P <sub>1</sub>	P <sub>2</sub>	P <sub>0</sub>	øD <sub>0</sub>	Т
ERJ2  ERJPA2  ERJ  ERJ  ERJ  ERJ	1005 (0402)	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05
ERJMFBA											0.60±0.05

<ul> <li>Chip resisto</li> </ul>	Chip resistor array / Anti-Sulfurated chip resistor Aarray / Chip attenuator											
Part No.	Size (inch)	Α	В	W	F	Е	P <sub>1</sub>	P <sub>2</sub>	P <sub>0</sub>	øD <sub>0</sub>	Т	
EXB14V	0806	0.70	0.95									
EXB14AT	(0302)	+0.10/-0.05	+0.05/-0.10									
EXB18V	1406 (0502)		1.60±0.10									
EXB24V EXBU24 EXB24AT	1010 (0404)	1.20±0.10	1.20±0.10	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05	
EXB28V EXBU28 EXBN8V	2010 (0804)		2.20±0.10									

Punched	Punched carrier taping (4 mm Pitch)												
● Chip resisto	Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / High power / High precision / Anti-Surge /												
Anti-Pulse /	Anti-Pulse / Anti-Sulfurated / High temperature												
Part No.	Size (inch)	Α	В	W	F	E	P <sub>1</sub>	P <sub>2</sub>	P <sub>0</sub>	$\phi D_0$	Т		
ERJ3 □ ERJ3LW(10mΩ) ERJ3BW ERJ□3 ERJ□3 □ ERA3□  ERJ3LW(5mΩ)	1608 (0603)	1.10±0.10	1.90±0.10								0.70±0.05		
ERJ6 ERJ 6 ERJ 6 ERJ 6 ERJ6 ERJ6	2012 (0805) 1220 (0508)	1.65±0.15	2.50±0.20	8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.84±0.05		
FKJ0RM	2012												

2012

(0805)

3216

(1206)

1632

(0612)

ERJ6LW

ERJ6CW ERJ8□ ERJ8□W

ERJ□□8

ERA8□ ERJB2

ERJD2

1.55±0.15

2.00±0.15

2.30±0.20

3.60±0.20

0.94±0.05

0.84±0.05

•	Chin resistor array	/ / Anti-Sulfurated chin resisto	or array / Chip resistor networks
•	Chip resistor arra	/ / Anti-Sunurated Chip resist	n array / Crip resistor networks

<ul> <li>Chip resistor array / Anti-Sulfurated chip resistor array / Chip resistor networks</li> </ul>												
Part No.	Size (inch)	Α	В	W	F	Е	P <sub>1</sub>	P <sub>2</sub>	P <sub>0</sub>	$\phi D_0$	T	
EXB34V EXBU34	1616 (0606)		1.95±0.20									
EXB38V EXBU38	3216 (1206)		3.60±0.20								0.70±0.05	
EXB2HV EXBU2H	3816 (1506)	1.95±0.15	4.10±0.15	8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	4.00±0.10 2.00±0.05	5 4.00±0.10	1.50		
EXBV4V	1616 (0606)		1.95±0.20							+0.10/0	0.84±0.05	
EXBV8V	3216 (1206)		3.60±0.20								0.04±0.05	
EXBD	3216 (1206)	2.00±0.20	3.60±0.20								0.84±0.10	
EXBQ	3816 (1506)	1.90±0.20	4.10±0.20	1							0.64±0.05	

# **Embossed carrier taping (1 mm Pitch)**

(:h	ın	resis	tors

• Only resistors													
Part No.	Size (inch)	Α	В	W	F	Е	P <sub>1</sub>	$P_2$	P <sub>0</sub>	$\phi D_0$	Т		
ERJXGN	0402 (01005)	0.25±0.05	0.45±0.05	4.00±0.20	1.80±0.05	0.90±0.10	1.00±0.10	1.00±0.10	2.00±0.10	0.80±0.10	0.5 max.		

## **Embossed carrier taping (4 mm Pitch)**

Chip resistors / Precision chip / Low resistance / High power / Anti-Surge / Anti-Pulse / Anti-Sulfurated

												Unit : mm
Part No.	Size (inch)	Α	В	W	F	E	P <sub>1</sub>	$P_2$	P <sub>0</sub>	$ \emptyset D_0 $	Т	$\phi D_1$
ERJ14□ ERJ□14	3225 (1210)	2.80±0.20	3.50±0.20	8.00±0.30	3.50±0.05							1.00 +0.10/0
ERJ12□ ERJ□12	4532 (1812)	3.50±0.20	4.80±0.20									
ERJ12Z ERJ12S ERJ□1D	5025 (2010)	- 2.80±0.20	5.30±0.20			1.75	4.00	2.00	4.00	1.50	1.00±0.10	
ERJB1 ERJC1 ERJD1	2550 (1020)	2.0010.20	3.3010.20	12.00 ±0.30	5.50±0.20	±0.10	±0.10	±0.05	±0.10	+0.10/0		15 min.
ERJ1T□ ERJ□1T ERJL1W	6432 (2512)	3.60±0.20	6.90±0.20								1.60±0.10	
ERJA1	3264 (1225)	3.50±0.20	6.80±0.20								1.10±0.20	

#### Current sensing resistors, Metal plate type

Init	mm
Ollic	

• Carront co.	nomig roototoro,	motal plate	typo									Unit : mm
Part No.	Size (inch)	Α	В	W	F	Е	P <sub>1</sub>	P <sub>2</sub>	P <sub>0</sub>	$\phi D_0$	Т	øD₁
ERJMP2 (1 mΩ)	3216 (1206)										1.55±0.20	_
ERJMP2 (2 mΩ)	3216 (1206)	1.90±0.20	3.50±0.20	8.00±0.30	3.50±0.10						1.40±0.20	_
ERJMP2 (3 to 50 mΩ)	3216 (1206)										1.10±0.20	_
ERJMP3 (1 to 2 mΩ)	5025 (2010)			40.00							1.55±0.20	_
ERJMP3 (3 to 50 mΩ)	5025 (2010)	2.90±0.20	5.40±0.20	12.00 ±0.30	5.50±0.10	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.15±0.20	_
ERJMB1	2550 (1020)										1.55±0.20	_
ERJMP4 (1 to 2 mΩ)	6432 (2512)										1.60±0.20	1.5 min.
ERJMP4 (3 to 50 mΩ)	6432 (2512)	3.50±0.20	6.90±0.20	12.00 ±0.30	5.50±0.10						1.20±0.20	_
ERJMS4	6432 (2512)	1									1.60±0.20	1.5 min.
ERJM1W	6432 (2512)										1.80±0.20	1.5 min.

### • Chip resistor array / Chip resistor networks

Unit	:	mm	

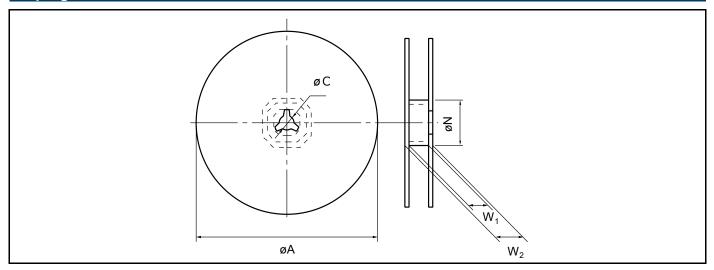
Part No.	Size (inch)	Α	В	W	F	Е	P <sub>1</sub>	P <sub>2</sub>	$P_0$	øD <sub>0</sub>	Т	øD <sub>1</sub>
EXBS8V	5022 (2009)	2.80±0.20	5.70±0.20			4.75	4.00	0.00	4.00	4.50	1.6 max.	
EXBE	4021 (1608)	2.50±0.20	4.40±0.20	12.00±0.30	5.50±0.20	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.10±0.20	1.5 min.
EXBA	6431 (2512)	3.50±0.20	6.80±0.20						_5.10	3.10/0	1.1010.20	

# **Embossed carrier taping (8 mm Pitch)**

● Current sensing resistors, Metal plate type Unit : mm												
Part No.	Size (inch)	Α	В	W	F	Е	P <sub>1</sub>	P <sub>2</sub>	P <sub>0</sub>	øD <sub>0</sub>	Т	øD <sub>1</sub>
ERJMS6	6468 (2526)	6.90±0.20	7.50±0.20	12.00	5.50±0.05	1.75	8.00	2.00	4.00	1.50	2.45±0.20	1.5 min.



# Taping reel



Unit: mm

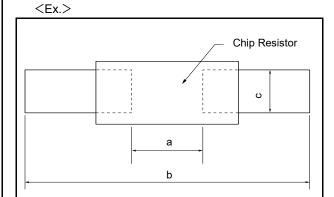
Tape width (W)			Dimensions					
rape widin (vv)	øΑ	øN	øС	W <sub>1</sub>	W <sub>2</sub>			
4 mm width	180.0±3.0			4.5±0.5	7.0±0.5			
8 mm width	180.0 0/-1.5	60.0+1.0/0	60.0+1.0/0	60.0+1.0/0	60.0+1.0/0	13.0±0.2	9.0+1.0/0	11.4±1.0
12 mm width	100.0 0/-1.5		13.0±0.2	13.0+1.0/0	15.4±1.0			
24 mm width	380.0±2.0	80.0±1.0		25.4±1.0	29.4±1.0			

Unit: mm



## Recommended land pattern

• An example of a land pattern for the rectangular type is shown below.



High power (double-sided resistive elements structure) type

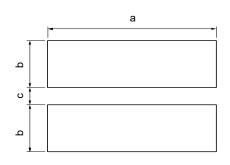
Part No.	Size	[	Dimensions		
i ait ivo.	(inch)	а	b	С	
ERJ2LW/2BW	1005 (0402)	0.52	1.4 to 1.6	0.4 to 0.6	
ERJ3LW/3BW	1608 (0603)	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1	
ERJ6LW		0.6 to 0.8	3.2 to 3.8	1.1 to 1.4	
ERJ6BW		0.9	3.2 to 3.8	1.1 to 1.4	
ERJ6CW (10 to 13 mΩ)	2012 (0805)	0.7 to 0.9	3.2 to 3.8	1.1 to 1.4	
ERJ6CW (15 to 30 mΩ)		0.9 to 1.1	3.2 to 3.8	1.1 to 1.4	
ERJ8BW					
ERJ8CW (10 to 16 mΩ)	3216 (1206)	1.2	4.4 to 5.0	1.3 to 1.8	
ERJ8CW (18 to 50 mΩ)		2.0 to 2.6	4.4 to 5.0	1.2 to 1.8	

Unit : mm

Size		Dimensions	
mm/inch	а	b	С
0402/01005	0.15 to 0.20	0.5 to 0.7	0.20 to 0.25
0603/0201	0.3 to 0.4	0.8 to 0.9	0.25 to 0.35
1005/0402	0.5 to 0.6	1.4 to 1.6	0.4 to 0.6
1608/0603	0.7 to 0.9	2.0 to 2.2	0.8 to 1.0
2012/0805	1.0 to 1.4	3.2 to 3.8	0.9 to 1.4
3216/1206	2.0 to 2.4	4.4 to 5.0	1.2 to 1.8
3225/1210	2.0 to 2.4	4.4 to 5.0	1.8 to 2.8
4532/1812	3.3 to 3.7	5.7 to 6.5	2.3 to 3.5
5025/2010	3.6 to 4.0	6.2 to 7.0	1.8 to 2.8
6432/2512	5.0 to 5.4	7.6 to 8.6	2.3 to 3.5
6432/2512*	3.6 to 4.0	7.6 to 8.6	2.3 to 3.5

<sup>\*</sup> ERJL1W

• An example of a land pattern for high power chip resistors / Wide terminal type is shown below.



			Unit : mm		
Part No.	Dimensions				
i ait ivo.	а	b	С		
ERJA1	6.4	1.70	0.60		
ERJB1					
ERJC1*1	5.0	1.30	0.75		
ERJD1*2					
ERJB2	3.2	0.95	0.70		
ERJD2*2	3.2	0.95	0.70		
ERJB3	2.0	0.80	0.60		

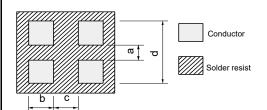
<sup>\*1:</sup> Anti-Sulfurated High power chip resistors / Wide terminal type

<sup>\*2:</sup> Low TCR High power chip resistors / Wide terminal type



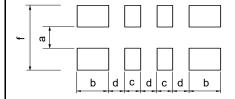
## Recommended land pattern

• An example of a land pattern for Chip Resistor Array, Anti-Sulfurated Chip Resistor Array and Chip Attenuator is shown below.



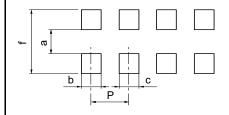
Part No.	Dimensions				
Fait No.	а	b	С	d	
EXB14V EXB14A	0.30	0.30	0.30	0.80 to 0.90	
EXB24V EXBU24 EXB24A	0.5	0.35 to 0.40	0.30	1.4 to 1.5	

Unit : mm

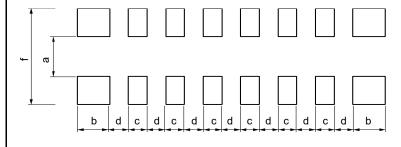


Part No.	Dimensions				
i ait ivo.	а	b	С	d	f
EXB28V EXBU28	0.40	0.525	0.25	0.25	1.40
EXBN8V	0.45 to 0.50	0.35 to 0.38	0.25	0.25	1.40 to 2.00

Unit : mm



David Na	Dimensions				
Part No.	а	b	С	f	Р
EXB18V	0.20 to 0.30	0.15 to 0.20	0.15 to 0.20	0.80 to 0.90	0.40
EXBV4V EXBV8V	0.7 to 0.9	0.4 to 0.45	0.4 to 0.45	2 to 2.4	0.80
EXB34V EXB38V EXBU34 EXBU38	0.7 to 0.9	0.4 to 0.5	0.4 to 0.5	2.2 to 2.6	0.80
EXBS8V	1 to 1.2	0.5 to 0.75	0.5 to 0.75	3.2 to 3.8	1.27



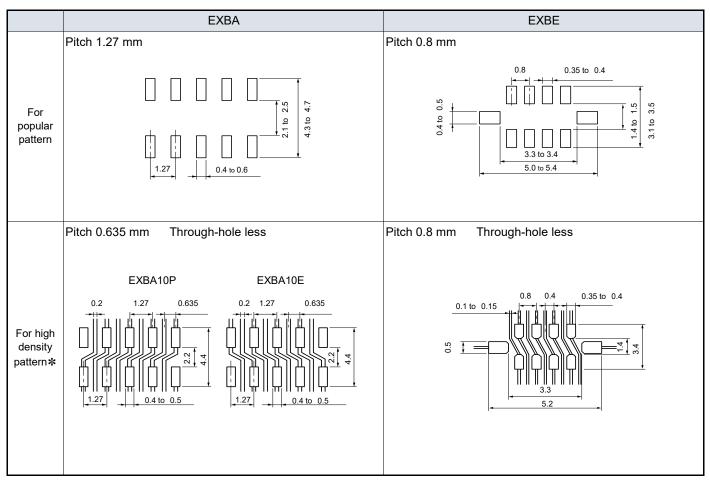
Unit:mm

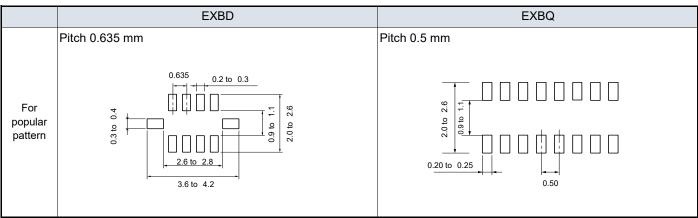
Part No.	Dimensions					
raitino.	а	b	С	d	f	
EXB2HV EXBU2H	1.00	0.425	0.25	0.25	2.00	



### **Recommended land pattern**

• An example of a land pattern for Chip Resistor Networks is shown below.





\* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.

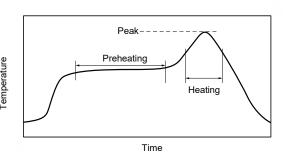


# Recommended soldering conditions (Rectagular type)

Recommendations and precautions are described below.

#### • Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



### For soldering (Example : Sn/Pb )

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

#### For lead-free soldering (Example : Sn/Ag/Cu)

	Temperature	Time
Preheating	150 ℃ to 180 ℃	60 s to 120 s
Main heating	Above 230 ℃	30 s to 40 s
Peak	max. 260 ℃	max. 10 s

#### Recommended soldering conditions for flow

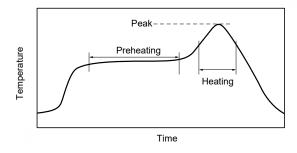
	For soldering		For lead-free soldering	
	Temperature	Time	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s	150 ℃ to 180 ℃	60 s to 120 s
Soldering	245 ± 5 ℃	20 s to 30 s	max. 260 ℃	max. 10 s

# Recommended soldering conditions (Chip resistor array / networks and Chip attenuator)

Recommendations and precautions are described below.

#### Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



#### For soldering (Example: Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

#### For lead-free soldering (Example : Sn/Ag/Cu)

	<u> </u>	0 /
	Temperature	Time
Preheating	150 ℃ to 180 ℃	60 s to 120 s
Main heating	Above 230 ℃	30 s to 40 s
Peak	max. 260 ℃	max. 10 s

### Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow sol der ing of EXBA series.



#### Standard for resistance value and resistance tolerance

#### Basis standard

IEC Publication 60062 : Marking codes for resistors and capacitors.

IEC Publication 60063 : Preferred number series forresistors and capacitors.

JIS C 5062 : Marking codes for resistors and capacitors.

JIS C 5063 : Preferred number series for resistors and capacitors.

#### Resistance values

The resistance values are notched by "Ratio" below in each series.

Series	Resistance tolerance (Standard)	Ratio	Remarks
E6	±20 %	6√10=1.46	
E12	±10 %	12√10=1.21	
E24	± 5 %	<sup>24</sup> √10=1.10	Please refer to standard resistance values shown on this catalog.
E48	± 2 %	48√10=1.05	,
E96	± 1%	<sup>96</sup> √10=1.02	

### How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is iden tified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10  $\Omega$ .

The examples of a three digit number

Resistance code	Value in ohms (Ω)	
R56	0.56	
5R6	5.6	
100	10	
271	270	
102	1 k	
273	27 k	
104	100 k	
275	2.7 M	
106	10 M	
107	100 M	

#### The examples of a four digit number

Resistance code	Value in ohms (Ω)	
R562	0.562	
5R62	5.62	
56R2	56.2	
1000	100	
2711	2.71 k	
1002	10 k	
2713	271 k	
1004	1 M	
2751	2.71 M	
1006	100 M	

### How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance code	Tolerance (%)	Examples
W	± 0.05	W1001 : 1000 Ω ± 0.05 %
В	± 0.1	B1001 : 1000 Ω ± 0.1 %
С	± 0.25	C1001 : 1000 Ω ± 0.25 %
D	± 0.5	D1001 : 1000 Ω ± 0.5 %
F	± 1	F1001 : 1000 Ω ± 1 %
G	± 2	G1001 : 1000 Ω ± 2 %
J	± 5	J101 : 100 Ω ± 5 %
K	± 10	K101 : 100 Ω ± 10 %
М	± 20	M101 : 100 Ω ± 20 %



# Standard resistance values

E6	E12	E24	E48	E96
		10	100	100
				102
			105	105
	10			107
		11	110	110
				113
			115	115
			115	118
10			121	121
		12	121	124
			107	127
			127	130
	12		122	133
		13	133	137
		13	140	140
			140	143
			147	147
	15	15		150
			154	154
		16		158
			162	162
				165
			169	169
				174
15		18	178	178
	18			182
			187	187
				191
			196	196
		20		200
			205	205
				210

E6	E12	E24	E48	E96
			215	215
		22		221
			226	226
				232
	22		237	237
				243
		24	249	249
		24	249	255
22			261	261
			201	267
			074	274
		27	274	280
			207	287
	27		287	294
			204	301
		30	301	309
			316	316
				324
	33	33	332	332
				340
			348	348
				357
		36	365	365
				374
33				383
			383	392
	39	39	402	402
				412
		43	422	422
				432
			442	442
				453

E6	E12	E24	E48	E96
		47	464	464
				475
	4-7		487	487
				499
	47	51	511	511
				523
		31	536	536
47			330	549
47			562	562
		56	302	576
		50	590	590
	56		590	604
	30		619	619
		63	019	634
		62	640	649
			649	665
		68	681	681
				698
			715	715
	68			732
			750	750
		75		768
			787	787
68				806
08		82	825	825
				845
			866	866
	82			887
	92	91	909	909
				931
			953	953
				976
	1			

# **Safty Precautions**

When using our products, no matter what sort of equipment they might be used for, be sure to confirm the applications and environmental conditions with our specifications in advance.



Panasonic Industry Co., Ltd. Device Solutions Business Division

1006 Kadoma, Kadoma City, Osaka 571-8506 Japan